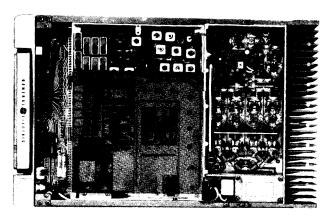


MASTR II MAINTENANCE MANUAL

25-50 MHz, 100-WATT TRANSMITTER

(MOBILE)



SPECIFICATIONS 3

Frequency Range

Power Output

Crystal Multiplication Factor

Frequency Stability
5C-ICOM with EC-ICOM
5C-ICOM or EC-ICOM
2C-ICOMS

Spurious and Harmonic Emission

Modulation

Modulation Sensitivity

Audio Frequency Characteristics

Distortion

Deviation Symmetry

Duty Cycle

Maximum Frequency Spread: (2 to 8 channels)

25-30 MHz 30-36 MHz 36-42 MHz 42-50 MHz 25-50 MHz

100 Watts (Adjustable from 50 to 100 Watts at 30 to 50 MHz, and from 75 to 100 Watts at 25 to 30 MHz)

3

±0.0005% (-40°C to +70°C) ±0.0002% (0°C to +55°C) ±0.0002% (-40°C to +70°C)

At least 85 dB below full rated power output

Adjustable from 0 to $\pm 5~\mathrm{kHz}$ swing with instantaneous modulation limiting.

80 to 120 Millivolts

Within +1 dB to -3 dB of a 6-dB/octave preemphasis from 300 to 3000 Hz per EIA standards. Post limiter filter per FCC and EIA.

Less than 2% (1000 Hz) Less than 3% (300 to 3000 Hz)

0.5 kHz maximum

EIA 20% Intermittent

Full Specifications

.160 MHz .320 MHz .200 MHz .400 MHz .240 MHz .470 MHz .280 MHz .540 MHz

1 dB Degradation

^{*}These specifications are intended primarily for the use of the serviceman. Refer to the appropriate Specification Sheet for the complete specifications.

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- WARNING -

Although the highest DC voltage in MASTR II Mobile Equipment is supplied by the vehicle battery, high currents may be drawn under short circuit conditions. These currents can possibly heat metal objects such as tools, rings, watchbands, etc., enough to cause burns. Be careful when working near energized circuits!

High-level RF energy in the transmitter Power Amplifier assembly can cause RF burns upon contact. KEEP AWAY FROM THESE CIRCUITS WHEN THE TRANSMITTER IS ENERGIZED:

DESCRIPTION

MASTR II transmitters are crystal-controlled phase modulated and designed for one-through eight-frequency operation in the 25 to 50 megahertz band. The solid state transmitter utilizes both integrated circuits (ICs) and discrete components, and consists of the following assemblies:

- Exciter Board; with audio, modulator, amplifier and multiplier stages.
- Power Amplifier Assembly; with amplifier, driver, PA, power control, filter and antenna switch.

CIRCUIT ANALYSIS

EXCITER

The exciter uses nine transistors and two integrated circuits to drive the PA assembly. The exciter can be equipped with up to eight Integrated Circuit Oscillator Modules (ICOMs). The ICOM crystal frequency ranges from approximately 8.33 to 16.67 megahertz, and the crystal frequency is multiplied three times (divided by four

and multiplied by 12 for a multiplication factor of three).

Audio, supply voltages and control functions are connected from the system board to the exciter board through P902.

Centralized metering jack J103 is provided for use with GE Test Set Model 4EX3All or Test Kit 4EX8K12. The test set meters the modulator, multiplier and amplifier stages.

ICOMS

Three different types of ICOMs are available for use in the exciter. Each of the ICOMs contains a crystal-controlled Colpitts oscillator, and two of the ICOMs contain compensator ICs. The different ICOMs are:

- 5C-ICOM contains an oscillator and a 5 part-per-million (±0.0005%) compensator IC. Provides compensation for EC-ICOMs.
- EC-ICOM contains an oscillator only. Requires external compensation from a 5C-ICOM.
- 2C-ICOM contains an oscillator and a
 2 PPM (±0.0002%) compensator IC. Will not provide compensation for an EC-ICOM.

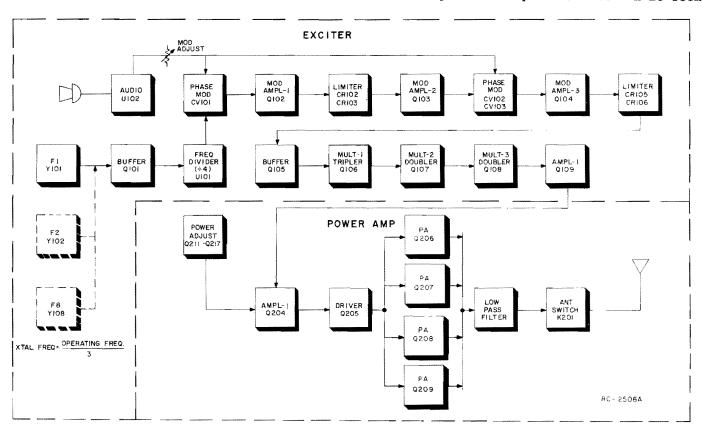


Figure 1 - Transmitter Block Diagram

The ICOMs are enclosed in an RF shielded can with the type ICOM (5C-ICOM, EC-ICOM or 2C-ICOM) printed on the top of the can. Access to the oscillator trimmer is obtained through a hole on the top of the can.

Frequency selection is accomplished by switching the ICOM keying lead (terminal 6) to A- by means of the frequency selector switch on the control unit. In single-frequency radios, a jumper from H9 to H10 in the control unit connects terminal 6 of the ICOM to A-. The oscillator is turned on by applying a keyed +10 Volts to the external oscillator load resistor. RF bypassing is provided for all unused keying loads in eight frequency radios. In two frequency radios the six unused keying leads are shorted to ground.

- CAUTION -

All ICOMs are individually compensated at the factory and cannot be repaired in the field. Any attempt to repair or change an ICOM frequency will void the warranty.

In standard 5 PPM radios using EC-ICOMs, at least one 5C-ICOM must be used. The 5C-ICOM is normally used in the receiver F1 position, but can be used in any transmit or receive position. One 5C-ICOM can provide compensation for up to 15 EC-ICOMs in the transmit and receiver. Should the 5C-ICOM compensator fail in the open mode, the EC-ICOMs will still maintain 2 PPM frequency stability from 0°C to 55°C (+32°F to 131°F) due to the regulated compensation voltage (5 Volts) from the 10-Volt regulator IC. If desired, up to 16 5C-ICOMs may be used in the radio.

The 2C-ICOMs are self-compensated at 2 PPM and will not provide compensation for EC-ICOMs.

Oscillator Circuit

The quartz crystals used in ICOMs exhibit the traditional "S" curve characteristics of output frequency versus operating temperature.

At both the coldest and hottest temperatures, the frequency increases with increasing temperature. In the middle temperature range (approximately 0°C to +55°C), frequency decreases with increasing temperature.

Since the rate of change is nearly linear over the mid-temperature range, the output frequency change can be compensated by choosing a parallel compensation capacitor with a temperature coefficient approximately equal and opposite that of the crystal.

Figure 2 shows the typical performance of an uncompensated crystal as well as the typical performance of a crystal which has been matched with a properly chosen compensation capacitor.

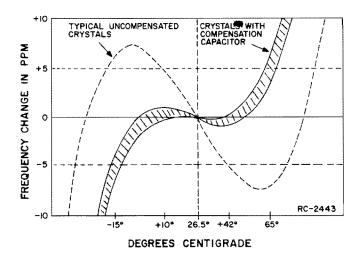


Figure 2 - Typical Crystal Characteristics

At temperatures above and below the mid-range, additional compensation must be introduced. An externally generated compensation voltage is applied to a varactor (voltage-variable capacitor) which is in parallel with the crystal.

A constant bias of 5 Volts (provided from Regulator IC U901 in parallel with the compensator) establishes the varactor capacity at a constant value over the entire midtemperature range. With no additional compensation, all of the oscillators will provide 2 PPM frequency stability from 0°C to 55°C (+32°F to 131°F).

Compensator Circuits

Both the 5C-ICOMs and 2C-ICOMs are temperature compensated at both ends of the temperature range to provide instant frequency compensation. An equivalent ICOM circuit is shown in Figure 3.

The cold end compensation circuit does not operate at temperatures above 0°C. When the temperature drops below 0°C, the circuit is activated. As the temperature decreases, the equivalent resistance decreases and the compensation voltage increases.

The increase in compensation voltage decreases the capacity of the varactor in the oscillator, increasing the output frequency of the ICOM.

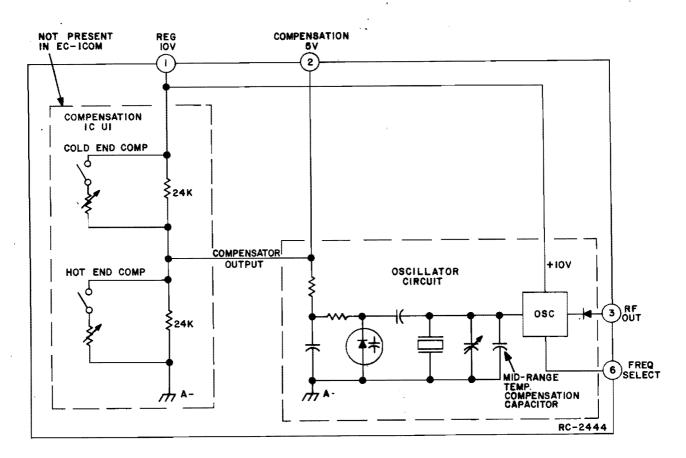


Figure 3 - Equivalent ICOM Circuit

The hot end compensation circuit does not operate at temperatures below +55°C. When the temperature rises above +55°C, the circuit is activated. As the temperature increases, the equivalent resistance decreases and the compensation voltage decreases. The decrease in compensation voltage increases the capacity of the varactor, decreasing the output frequency of the ICOM.

SERVICE NOTE: Proper ICOM operation is dependent on the closely-controlled input voltages from the 10-Volt regulator. Should all of the ICOMs shift off frequency, check the 10-Volt regulator module.

AUDIO IC

The transmitter audio circuitry is contained in audio IC UlO2. A simplified drawing of the audio IC is shown in Figure 4.

Audio from the microphone at pin 12 is coupled through pre-emphasis capacitor C1 to the base of Q1 in the operational amplifier-limiter circuit. Collector voltage for the transistorized microphone preamplifier is supplied from pin 11 through microphone collector load resistor R18 to pin 12.

The operational amplifier-limiter circuit consists of Q1, Q2 and Q3. Q3 provides limiting at high signal levels. The gain of the operational amplifier circuit is fixed by negative feedback through R19, R20 and the resistance in the network (pin 9).

The output of Q3 is coupled through a de-emphasis network (R10 and C3) to an active post-limiter filter consisting of C4, C5, C6, R11, R12, R13, R15, R17, and Q4.

Following the post-limiter filter is class A amplifier Q5. The output of Q5 is coupled through MOD ADJUST potentiometer R127 to the phase modulators.

SERVICE NOTE: If the DC voltages to the Audio IC are correct and no audio output can be obtained, replace Ul02.

For radios equipped with Channel Guard, tone from the encoder is applied to the phase modulators through CHANNEL GUARD MOD ADJUST potentiometer R128, and resistors R110, R121 and R124. Instructions for setting R128 are contained in the modulation adjustment section of the Transmitter Alignment Procedure.

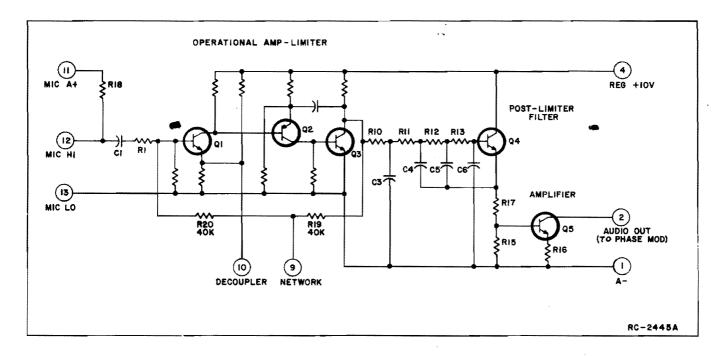


Figure 4 - Simplified Audio IC

FREQUENCY DIVIDER IC

The output at pin 3 of the selected ICOM is coupled through buffer amplifier Q101 to frequency divider U101, which divides the oscillator frequency by 4. The divider consists of two J-K flip-flops connected as a binary counter.

When the transmitter is not keyed (no ICOMs on), Q101 is saturated (turned on) with its collector voltage near zero. Keying the transmitter starts one of the ICOMs, and its output cuts Q101 on and off once each cycle. As Q101 turns off during each cycle, the drop in collector voltage causes the left flip-flop to change state. Assume the flip-flop was in the "0" state (the output at "Q" near A-). The first cycle of the oscillator output causes it to switch to the "1" stage (output at "Q" approximately 5 Volts). The second cycle will cause the flip-flop to switch back to the "0" state. Therefore, it requires two oscillator cycles to switch the left flip-flop through one complete cycle from "0" to "1" and back to "0".

When the left flip-flop switches from "1" to "0", it causes the right flip-flop to change state. It requires two cycles of the left flip-flop to switch the right flip-flop from "0" to "1" and back to "0". Therefore, four cycles of the oscillator output are required for each cycle of output from pin 9 of Ul01.

If U101 was operating into a pure resistive load, its output would be a square wave. However, the modulator circuit presents a tuned load to the IC, so that harmonics are filtered out and the waveform at the junction of C102 and C103 (modulator input) is essentially a sine wave at one-fourth the oscillator frequency. The output of the frequency divider is coupled through DC blocking capacitor C102 to the first modulator stage.

PHASE MODULATORS, AMPLIFIER & MULTIPLIERS

The first phase modulator is varactor (voltage-variable capacitor) CV101 in series with tunable coil L101. This network appears as a series-resonant circuit to the RF output of the oscillator. An audio signal applied to the modulator circuit through blocking capacitor C115 varies the bias of CV101, resulting in a phase modulated output. A voltage divider network (R108 and R109) provides the proper bias for varactors CV101, CV102 and CV103.

The output of the first modulator is coupled through blocking capacitor C106 to the base of Class A amplifier Q102. The first modulator stage is metered through a metering network consisting of R115, R150, C107 and CR101. Diodes CR102 and CR103 remove any amplitude modulation in the modulator output.

Following Q102 is another Class A Ampli- RF AMPLIFIERS fier, Q103. The output of Q103 is applied to the second modulator stage. The second modulator consists of two cascaded modulator circuits consisting of CV102, L102, L103 and CV103. Following the second modulator is a Class A amplifier Q104. The output of the second modulator stage is metered through R133, R145, C117 and CR104, and is applied to the base of buffer Q105. Diodes CR105 and CR106 remove any amplitude modulation in the second modulator output.

Buffer Q105 is saturated when no RF signal is present. Applying an RF signal to Q105 provides a sawtooth waveform at its collector to drive the class C tripler, Q106. The tripler stage is metered through R146. The output of Q106 is coupled through tuned circuits T101, T102 and T103 to the base of doubler Q107. T101, T102 and T103 are tuned to one-fourth of the operating frequency. The doubler stage is metered through R147.

The output of Q107 is coupled through tuned circuits T104 and T105 to the base of second doubler Q108. T104 and T105 are tuned to one-half the operating frequency. Q108 is metered through R148.

The output of Q108 is coupled through three tuned circutts (T106, T107 and T108) to the base of amplifier Q109. The circuits are tuned to the transmitter operating frequency.

Q109 is a class C amplifier with a collector feed network consisting of C139, C141, L104, L108 and R143. The stage is metered through R149. The amplifier collector circuit consists of C142, C143, C146 and L105, and matches the amplifier output to the input of the power amplifier assembly.

POWER AMPLIFIER

The PA assembly uses six RF power transistors and seven transistors in the Power Control circuitry to provide a power output of 100 Watts. The broadband PA has no adjustments other than Power Control potentiometer R261.

Supply voltage for the PA is connected through power leads from the system board to feedthrough capacitors C297 and C298 on the bottom of the PA assembly. C297, C298 and C299, L297 and L298 prevent RF from getting on the Power leads. Diode CR295 will cause the main fuse in the fuse assembly to blow if the polarity of the power leads is re-

Centralized metering jack J205 is provided for use with GE Test Set Model 4EX3A11 or Test Kit 4EX8Kl2. The Test Set meters the Ampl-1 drive (exciter output), Ampl-1 power control, Driver and PA current. L251 through L257 in conjunction with bypass capacitors C4210 through C4216 keep RF off of the metering leads.

The exciter output is coupled through an RF cable to PA input jack J201. RF from the exciter is coupled through DC blocking capacitor C201 to the base of Class C amplifier Q204 through a matching network. The network matches 50-ohm input to the base of Q204, and consists of C205, C206, C207, L201 and L202. R203 and R204 lower the gain of the amplifier stage.

Part of the RF input is rectified by CR201 and used to activate the Power Control circuit. Another portion of the rectified RF is applied to voltage dividers R201 and R202 for metering the Ampl-1 drive at J205.

Collector voltage to Q204 (Ampl-1) is controlled by the Power Control Circuit, and is applied through a collector stabilizing network consisting of L258 and R272 and collector feed network L205 and C213. The collector voltage of Q204 is metered through R271 at J205.

Following Q204 is a matching network (C208 through C212, L204 and L206) to a resistive pad (R207, R208 and R209). The output of the resistor network is applied to the base of the Class C driver (Q205) through a matching network consisting of C218, C219, C220, L207 and L208. Resistors R207 through R215 lower the gain of driver Q205.

Collector voltage to Q205 is coupled through a collector stabilizing network consisting of L259 and R273 and collector feed network L211 and C226. Collector current for Q205 is metered across tapped manganin resistor R249 at J205 (DRIVER CURRENT). The reading is taken on the one-Volt scale with the High Sensitivity button pressed. and read as 10 amperes full scale.

Following Q205 is a matching network (C221 through C225, L210 and L214) that matches the driver output to the input of the first power divider circuit (C230, C231, L214, L215 and L216).

The power amplifier stages consist of four identical paralleled Class C amplifiers (Q206 through Q209). The output of the first power divider circuit is applied to four additional power dividers. C234-L217 and C235-L218 provide drive for Q206 and Q207, while C236-L219 and C237-L220 provide drive for Q208 and Q209.

The output of C234-L217 is applied to the base of Q206 an impedance-matching network (L217, L221, C238, C242 and C243). Resistors R220 through R223, R236 and R237 lower the gain of Q206. Supply voltage for Q206 is coupled through a collector-stabilizing network consisting of L260 and R274 and collector feed network L223 and C270.

Collector current for Q206 through Q209 is metered across tapped maganin resistors R250 and R251 at J205 (PA CURRENT). The

reading is taken on the one-Volt scale with the High Sensitivity button pressed, and read as 30 amperes full scale.

The output of Q206 is coupled through a matching network (C250, C251, L229, C258, C259, C266 and L237), applied to a lumped-constant combiner circuit (C280, L237 and L241), and added to the output of Q207. The outputs of Q206 and Q207 are added to the outputs of Q208 and Q209 through lumped-constant power combiner circuit C284, L249, C294, L250 and C285. The combined PA output is applied to 50-ohm microstrip W205, and then to an M-derived, constant K low-pass filter. The filter output is applied to the antenna through antenna switch K201.

Capacitors C286 through C293, C217, C228 and C233 provide ground isolation for \pm ground operation.

— WARNING —

The stud mounted RF Power Transistors used in the transmitter contain Beryllium Oxide, a TOXIC substance. If the ceramic, or other encapsulation is opened, crushed, broken or abraded, the dust may be hazardous if inhaled. Use care in replacing transistors of this type.

POWER CONTROL CIRCUIT

When the transmitter is keyed, rectified RF from CR201 is applied to the base of switch Q211, turning it on. Turning on Q211 turns on voltage regulator Q212 which supplies a constant voltage to Power Adjust potentiometer R261.

Q215, Q216 and Q217 operate as an amplifier chain to supply voltage to the collector of Q204 (Ampl-1). The setting of R261 determines the voltage applied to the base of Q215. The higher the voltage at the base of Q215, the harder the amplifiers conduct, supplying more collector voltage to Q204. The lower the voltage at the base of Q215, the less collector voltage is supplied to Q204. Reducing the supply voltage to Q204 reduces the drive to Q205, thereby reducing the power output of the PA. The power output can be adjusted by R261 from approximately 50 to 100 Watts (75 to 100 Watts at 25-30 MHz).

Temperature protection is provided by Q213, Q214, and thermistor RT201 which is mounted in the PA heatsink. Under normal operating conditions, the circuit is inactive (Q213 is on and Q214 is off). When the heatsink temperature reaches approximately 100°C, the resistance of RT201 decreases. This increases the base voltage applied to Q213, turning it off. Turning off Q213 allows Q214 to turn on, decreasing the voltage at Power Adjust potentiometer R261. This reduces the base voltage to Q215 which causes Q216 and Q217 to conduct

less, reducing the collector voltage to Q204 (Ampl-1). This reduces the transmitter output power, keeping the heatsink at a maximum of approximately 100°C. When the heatsink temperature decreases below 100°C, the temperature control circuit turns off, allowing the normal transmitter power output.

CARRIER CONTROL TIMER

The Carrier Control Timer option shuts off the transmitter on each transmission after a one-minute timing cycle, and alerts the operator that the transmitter is off by means of an alarm tone in the speaker. The transmitter can be turned on again by releasing and keying the push-to-talk switch on the microphone.

The timing cycle (transmitter keyed time) is normally set at the factory for a duration of one minute. A potentiometer permits the timing cycle to be adjusted from approximately 15 seconds to 3 minutes.

MAINTENANCE

DISASSEMBLY

To service the transmitter from the top:

 Pull the locking handle down, then pry up the top cover at the front notch and lift off the cover.

To service the transmitter from the bottom:

- 1. Pull the locking handle down and pull the radio out of the mounting frame.
- 2. Remove the top cover, then loosen the two bottom cover retaining screws and remove the bottom cover (see Figure 5).
- 3. To gain access to the bottom of the exciter board, remove the six screws

 (A) holding the exciter board and its bottom cover to the module mounting frame, and remove the bottom cover.

To remove the exciter board from the radio:

- 1. Unplug the exciter/PA cable (B) .
- 2. Remove the six screws (A) holding the exciter board and its bottom cover to the module mounting frame (see Figure 6).
- 3. Press straight down on the plug-in exciter from the top to avoid bending the pins when unplugging the board from the system board jack.

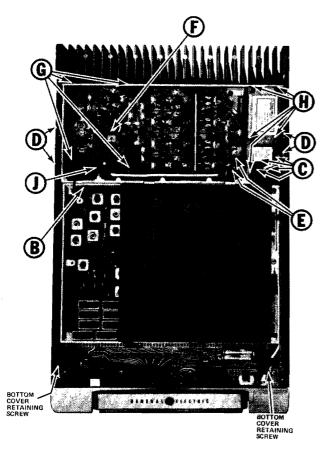


Figure 5 - Disassembly Procedure-Top View

To remove the PA assembly:

- 1. Remove the PA top cover and unplug the exciter/PA cable (B), the antenna, receiver and PTT cables (C).
- 2. Remove the four side-rail screws D, and unsolder the power cables from the bottom of the PA assembly if desired.

To remove the PA board:

- 1. Remove the PA top cover and unplug the exciter/PA cable (B) .
- 2. Unsolder the two feedthrough coils $\stackrel{\textstyle (E)}{}$ and the thermistor leads $\stackrel{\textstyle (F)}{}$.
- Remove the PA transistor hold-down nuts and spring washers on the bottom of the PA assembly.
- 4. Remove the four PA board mounting screws

 (G), the five screws in the filter casting (H), and the retaining screw in Q210 (J), and lift the board out.

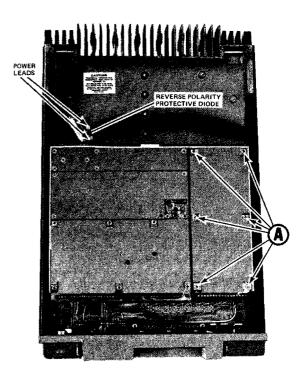


Figure 6 - Disassembly Procedure-Bottom View

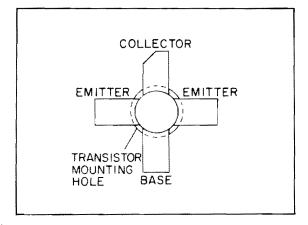
— WARNING -

PA TRANSISTOR REPLACEMENT

The stud mounted RF Power Transistors used in the transmitter contain Beryllium Oxide, a TOXIC substance. If the ceramic or other encapsulation is opened, crushed, broken or abraded, the dust may be hazardous if inhaled. Use care in replacing transistors of this type.

To replace the PA RF transistors:

- 1. Unsolder one lead at a time with a 50-Watt soldering iron. Use a scribe to hold the lead away from the printed circuit board until the solder cools.
- 2. Turn the transmitter over.
- 3. Hold the body of the transistor to prevent it from turning. Remove the transistor hold-down nut and spring washer through the hole in the heatsink with an 11/32-inch nut-driver. Lift out the transistor, and remove the old solder from the printed circuit board with a de-soldering tool such as a SOLDA PULLT®. Special care should be taken to prevent damage to the printed circuit board runs.



SOLDER ENTIRE LEAD FROM EDGE
OF MOUNTING HOLE TO END OF LEAD

TRANSISTOR 7 SOLDER LENGTH
LEAD PRINTED
BOARD
TRANSMITTER
HEATSINK

HOLD-DOWN NUT &
SPRING WASHER

RC-2309

Figure 7 - Lead Identification

- 4. Trim the new transistor leads (if required) to the lead length of the removed transistor. Cut the collector lead at a 45° angle for future identification (see Figure 7). The letter "C" on the top of the transistor indicates the collector.
- 5. Apply a coating of silicon grease around the transistor mounting surface, and place the transistor in the mounting hole. Align the leads as shown in the Outline Diagram. Then hold the body of the transistor and replace the holding-down nut and spring-washer using moderate torque (8 inch-pounds). A torque wrench must be used for this adjustment since transistor damage can result if too little or too much torque is used.

Figure 8 - Lead Forming

- 6. Make sure that the transistor leads are formed as shown in Figure 8 so that the leads can be soldered to the printed circuit pattern, starting from the inner edge of the mounting hole.
- 7. Solder the leads to the printed circuit pattern. Start at the inner edge of mounting hole and solder the remaining length of transistor lead to the board. Use care not to use excessive heat that causes the printed wire board runs to lift up from the board. Check for shorts and solder bridges before applying power.

- CAUTION -

Failure to solder the transistor leads as directed may result in the generation of RF loops that could damage the transistor or may cause low power output.

MOBILE RADIO DEPARTMENT
GENERAL ELECTRIC COMPANY • LYNCHBURG, VIRGINIA 24502



MODULATION LEVEL ADJUSTMENT

The MOD ADJUST (R127) was adjusted to the proper setting before shipment and should not normally require readjustment. This setting permits approximately 75% modulation for the average voice level. The audio peaks which would cause overmodulation are clipped by the modulation limiter. The limiter, in conjunction with the de-emphasis network, instantaneously limits the slope of the audio wave to the modulator, thereby preventing overmodulation while preserving intelligibility.

TEST EQUIPMENT

- 1. An audio oscillator (GE Model 4EX6A10)
- 2. A frequency modulation monitor
- 3. An output meter or a VTVM
- 4. GE Test Set Models 4EX3All or 4EX8Kl2

PROCEDURE

- 1. Connect the audio oscillator and the meter across audio input terminals J10 (Green-Hi) and J11 (Black-Lo) on GE Test Set, or across P902-6 (Mike High) through a 0.5 microfarad (or larger) DC blocking capacitor, and P902-5 (Mike-Low) on the System Board.
- 2. Adjust the audio oscillator for 1-Volt RMS at 1000 Hz.
- 3. For transmitters without Channel Guard, set MOD ADJUST R127 for a 4.5-kilo-hertz swing with the deviation polarity which gives the highest reading as indicated on the frequency modulation monitor.
- 4. For transmitters with Channel Guard, set Channel Guard MOD ADJUST R128 for zero tone deviation. Next, with the 1-Volt signal at 1000 Hz applied, set MOD ADJUST R127 for a 3.75 kHz deviation. Then remove the signal from the audio oscillator and set Channel Guard MOD ADJUST R128 for 0.75 kHz tone deviation.
- 5. For multi-frequency transmitters, set the deviation as described in Steps 3 or 4 on the channel producing the largest amount of deviation.

PA POWER INPUT

For FCC purposes, the PA power input can be determined by measuring the PA supply voltage and PA current, and using the following formula:

P; = PA voltage x PA current

where:

P, is the power input in Watts,

PA voltage is measured with Test Set Model 4EX3All in Position G on the 15-Volt range (read as 15 Volts full scale), and with the polarity switch in the (-) position. With Test Set Model 4EX8Kl2, use the B+ position and the 1-Volt range (read as 15 Volts full scale), with the HIGH SENSITIVITY button pressed and the polarity switch in the (-) position.

PA current is measured with the Test Set in Position G in the Test 1 position, and with the HIGH SENSITIVITY button pressed (30 amperes full scale).

Example

 $P_i = 12.4 \text{ Volts x } 8.5 \text{ amperes} = 105.4 \text{ Watts}$

ICOM FREQUENCY ADJUSTMENT

First, check the frequency to determine if any adjustment is required. The frequency should be set with a frequency meter or counter with an absolute accuracy that is 5 to 10 times better than the tolerance to be maintained, and with the entire radio as near as possible to an ambient temperature of 26.5°C (79.8°F).

 ${\tt MASTR}$ II ICOMs should be reset only when the frequency shows deviations in excess of the following limits:

- A. ± 0.5 PPM, when the radio is at 26.5°C (79.8°F).
- . ± 2 PPM at any other temperature within the range of -5°C to +55°C (+23°F to +131°F).
- C. The specification limit (± 2 PPM or ± 5 PPM) at any temperature within the ranges of $-40\,^{\circ}\text{C}$ to $-5\,^{\circ}\text{C}$ ($-40\,^{\circ}\text{F}$ to $+23\,^{\circ}\text{F}$) or $+55\,^{\circ}\text{C}$ to $+70\,^{\circ}\text{C}$ ($+131\,^{\circ}\text{F}$ to $+158\,^{\circ}\text{F}$).

If the radio is at an ambient temperature of $26.5^{\circ}C$ (79.8°F), set the oscillator for the correct operating frequency.

If the radio is not at an ambient temperature of 26.5°C, setting errors can be minimized as follows:

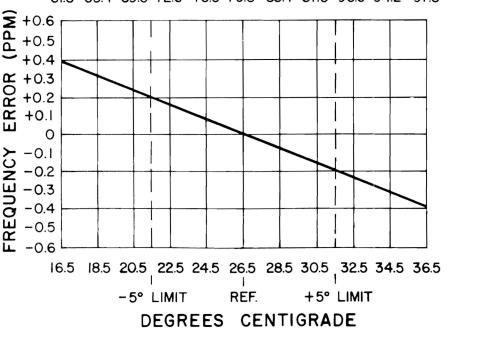
- A. To hold setting error to ± 0.6 PPM (which is considered reasonable for 5 PPM ICOMS):
 - 1. Maintain the radio at 26.5 $^{\circ}\text{C}$ $(\pm5\,^{\circ}\text{C})$ and set the oscillator to desired frequency, or-
 - 2. Maintain the radio at $26.5^{\circ}C$ ($\pm10^{\circ}C$) and offset the oscillator, as a function of actual temperature, by the amount shown in Figure 9.
- B. To hold setting error to ± 0.35 PPM (which is considered reasonable for 2 PPM ICOMs): Maintain unit at 26.5°C (± 5 °C) and offset the oscillator, as a function of actual temperature, by the amount shown in Figure 9.

For example: Assume the ambient temperature of the radio is 18.5° C (65.4°F). At that temperature, the curve shows a correction factor of 0.3 PPM. (At 25 MHz, 1 PPM is 25 Hz. At 50 MHz, 1 PPM is 50 Hz).

With an operating frequency of 50 MHz, set the oscillator for a reading of 15 Hz $(0.3 \times 50 \text{ Hz})$ higher than the licensed operating frequency. If a negative correction factor is obtained (at temperatures above 26.5°C), set the oscillator for the indicated PPM lower than the licensed operating frequency.

DEGREES FAHRENHEIT

61.8 65.4 69.0 72.6 76.6 79.8 83.4 87.0 90.6 94.2 97.8



RC-2453

METERING

JACK J103

ADJUST -

CHANNE

GUARD

MOD ADJUST

R128

R127

TRANSMITTER ALIGNMENT

EQUIPMENT REQUIRED

SYSTEM BOARD

ANTENNA

JACK

METERING

METERING

JACK J205

GENERALSE

- GE Test Set Model 4EX3All or Test Kit 4EX8Kl2.
- 2. A 50-ohm was tmeter connected to antenna jack J906.
- 3. A frequency counter.

PRELIMINARY CHECKS AND ADJUSTMENTS

- 1. Place ICOMs on Exciter Board (crystal frequency = operating frequency ÷ 3).
- For a large change in frequency or a badly mis-aligned transmitter, pre-set the slugs in T101 through T108, and L101, L102 and L103 to the bottom of the coil form.

NOTE	
The tuning frequency for multi-frequency transmitters is determined by the operating frequency and the frequency spread between	
transma tters. Refer to the table below for maximum frequency spread.	

3. For multi-fy-equency transmitters with a frequency spread less than that specified in column (1), tune the transmitters to the lowest frequency.

For frequency spread exceeding the limits specified in column (1), tune the transmitters using a center frequency tune up ICOM. Except the maximum frequency spread can be extended to the limits specified in column (3) with 1 dB degradation.

For tuning 1.701, L102, L103, Always tune L101, L102, L103 on the lowest frequency.

Multi-frequency Transmitter Tuning												
Transmitter Frequency Range	MAXIMUM FREQUENCY SPREAD											
	(1) without center tuning	with center tuning	with center tuning (1dB degradation)									
25 - 30 MHz	.080 MHz	.160 MHz	.320 MHz									
30 - 36 MHz	.100 MHz	.200 MHz	.400 MHz									
36 - 42 MHz	.120 MHz	.240 MHz	.470 MHz									
42 - 50 MHz	.140 MHz	.280 MHz	.540 MHz									

- 4. Connect the red plug on the GE Test Set to the System Board metering jack, and the black plug to the Exciter metering jack. Set the polarity to +, and set the range to the Test 1 position (1-Volt position for 4EX8K12) for all adjustments. NOTE: With the Test Set connected to the PA metering mack, the voltage reading at position "F" with the HIGH SENSITIVITY button pressed may be converted to driver collector current by reading the current as 10 amperes full scale. The voltage reading at position "G" with the HIGH SENSITIVITY button pressed may be converted to PA collector current by reading the current as 30 amperes full scale.
- 5. All adjustments are made with the transmitter keyed. Unkey the transmitter between steps to avoid unnecessary heating.

STEP	METTER POSITION	TUNING CONTROL	METER READING	PROCEDURE
1.	A MOD-1	L101	Maximum	Tune L101 for maximum meter reading.
2.	В	L102 & L103	Maximum	Tune L102 and then L103 for the maximum meter reading.
3.	C MULT-1	T101 & T102	See Procedure	Tune L101 for a dip in meter reading, and then tune T102 for maximum meter reading.
4.	D AULT-2	T103, T102, T101 & T104	See Procedure	Tune T103 for maximum meter reading and re-adjust T102 and T101 for maximum meter reading. Then tune T104 for a dip in meter reading.
5.	F AULT-3	T105, T104, T106 & T107	See Procedure	Tune T105 for maximum meter reading and re-adjust T104 for maximum meter reading. Then tune T106 for a dip in meter reading and T107 for maximum meter reading.
6.	G MPL-1	T108, T107 & T106	See Procedure	Tune T108 for maximum meter reading, and then re-adjust T107 and T106 for maximum meter reading.
7.	D #MPL-1 DRIVE on PA)	C143, C156	Maximum	Move the black metering plug to the Power Amplifier metering jack and tune C143 and C156 for maximum meter reading.
8.		R261		With the battery voltage at 13.4 Volts or the PA collector voltage at 12.4 Volts, set Power Adjust potentiometer R261 on the PA board for the desired power output (from 50 to 100 Watts at 30-50 MHz, or from 75 to 100 Watts at 25-30 MHz). If the battery voltage is not at 13.4 Volts or the collector voltage at 12.4 Volts and full rated output is desired (50 to 100 Watts at 30-50 MHz, or from 75 to 100 Watts at 25-30 MHz), set R261 for the output power according to the battery voltage or collector voltage shown in Figure 10.
			v.	The PA collector voltage is measured as described in the PA POWER INPUT section.

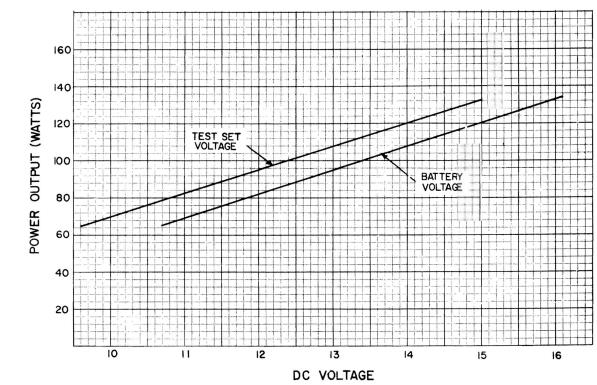


Figure 10 - Power Output Setting Chart

ALIGNMENT PROCEDURE

25-50 MHz, 100-WATT TRANSMITTER

Issue 1

TEST PROCEDURES

These Test Procedures are designed to assist you in servicing a transmitter that is operating—but not properly. Problems encountered could be low power output, tone and voice deviation, defective audio sensitivity, and modulator adjust control set too high. Once a defect is pin-pointed,

refer to the "Service Check" and the additional corrective measures included in the Transmitter Troubleshooting Procedure. Before starting with the Transmitter Test Procedures, be sure the transmitter is tuned and aligned to the proper operating frequency.

CAUTION —

Before bench testing the MASTR II Mobile Radio, be sure of the output voltage characteristics of your bench power supply.

To protect the transmitter power output transistors from possible instant destruction, the following input voltages must not be exceeded:

Transmitter unkeyed: 20 Volts
Transmitter keyed (50 ohm resistive load): 18 Volts
Transmitter keyed (no load or non-resistive load): 15.5 Volts

These voltages are specified at the normal vehicle battery terminals of the radio and take the voltage drop of standard cables into account. The voltage limit shown for a non-optimum load is for "worst case" conditions. For antenna mismatches likely to be encountered in practice, the actual limit will approach the 18 Volt figure.

Routine transmitter tests should be performed at EIA Standard Test Voltages (13.6 VDC for loads of 6 to 16 amperes; 13.4 VDC for loads of 16 to 36 amperes). Input voltages must not exceed the limits shown, even for transient peaks of short duration.

Many commonly used bench power supplies cannot meet these requirements for load regulation and transient voltage suppression. Bench supplies which employ "brute force" regulation and filtering (such as Lapp Model 73) may be usable when operated in parallel with a 12-Volt automotive storage battery.

TEST EQUIPMENT REQUIRED

for test hookup as shown:

1. Wattmeter similar to: 2. VTVM similar to: 3. Audio Generator similar to:

Bird # 43 Jones # 711N

Measurements # 720

Triplett # 850 Heath # IM-21 GE Model 4EX6Al0

4. Deviation Meter (with a .75 kHz scale) similar to:

5. Multimeter similar to:

GE TEST SET MODEL 4EX3A11, MODEL 4EX8K12 or 20,000 ohms-per-Volt voltmeter

POWER MEASUREMENT

TEST PROCEDURE

- 1. Connect transmitter output from the antenna jack to the wattmeter through a 50-ohm coaxial cable. Make sure the wattmeter is terminated into a 50-ohm load.
- 2. Key the transmitter and check the wattmeter for the desired power output.

SERVICE CHECK

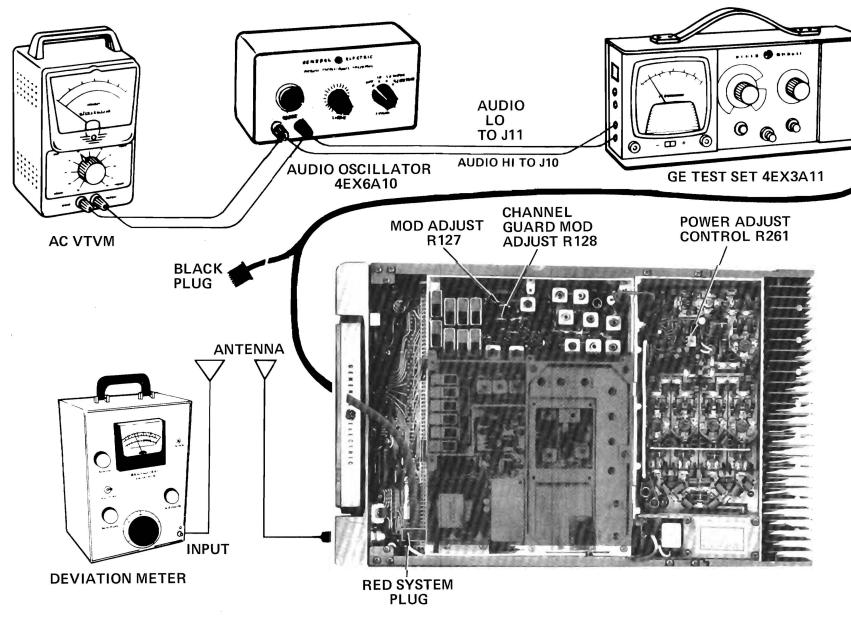
Check the setting of the Power Adjust Control (R261).

Refer to the QUICK CHECKS on the Transmitter Troubleshooting Procedure.

VOICE DEVIATION, SYMMETRY AND AUDIO SENSITIVITY

TEST PROCEDURE

- 1. Connect the test equipment to the transmitter as shown.
- 2. In radios with Channel Guard, set Channel Guard Mod Adjust R128 for zero tone deviation.
- 3. Set the Audio generator output to 1.0 VOLTS RMS and frequency to 1 kHz.
- 4. Key the transmitter and adjust Deviation Meter to carrier frequency.
- 5. Deviation reading should be ± 4.5 kHz in radios without Channel Guard, and ± 3.75 kHz in radios with Channel Guard.
- 6. If necessary, adjust MOD ADJUST control R127 for the proper deviation on plus (+) or minus (-) deviation, whichever is greater.
- NOTES: -- MASTR II transmitters are adjusted for 4.5 kHz deviation at the factory. The factory adjustment will prevent the transmitter from deviating more than 5.0 kHz under the worst conditions of frequency, voltage and temperature.
- 7. If the deviation reading plus (+) or minus (-) differs by more than 0.5 kHz, recheck Steps 1 and 2 as shown in the Transmitter Alignment Chart.
- 8. Check Audio Sensitivity by reducing generator output until deviation falls to 3.0 kHz for radios without Channel Guard, or 2.25 kHz for radios with Channel Guard. Voltage should be LESS than 120 millivolts. If not, refer to the Transmitter Troubleshooting Procedure.



TONE DEVIATION WITH CHANNEL GUARD

TEST PROCEDURE

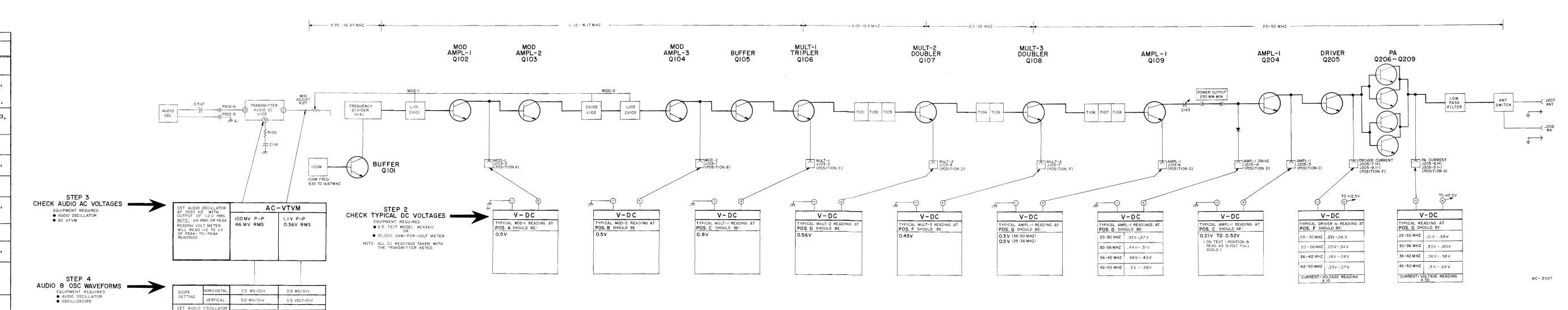
- 1. Set up the Deviation Meter and monitor the output of the transmitter.
- 2. Remove the 1000 Hz signal from the audio generator.
- 3. Key the transmitter and check for 0.75 kHz deviation. If the reading is low or high, adjust Channel Guard MOD ADJUST R128 for a reading of 0.75 kHz.

NOTES:

- 1. On units supplied with Channel Guard, the Phase Modulator Tuning should be adjusted carefully to insure proper performance. (Refer to Steps 1 and 2 in the Transmitter Alignment Chart).
- 2. The Tone Deviation Test Procedures should be repeated every time the Tone Frequency is changed.

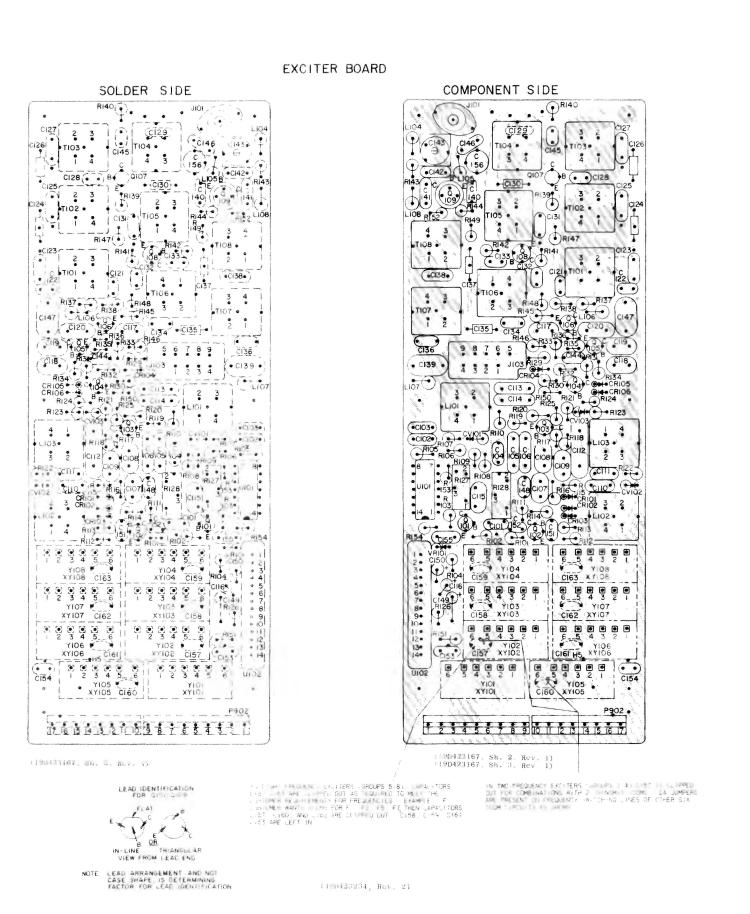
STEP I - QUICK CHECKS

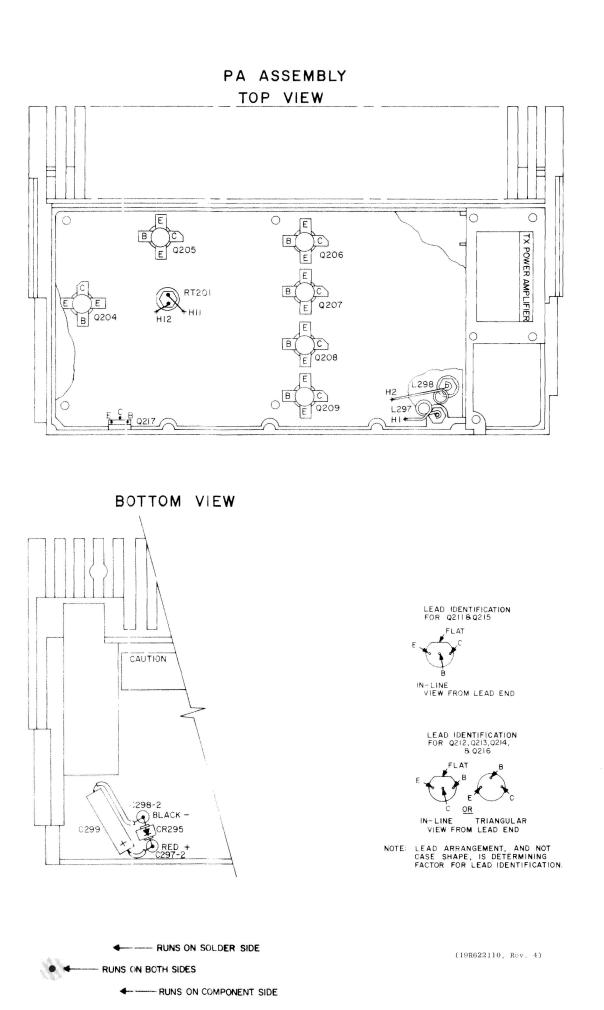
METER PROBABLE DEFECTIVE STAGE												
POSITION GE TEST SET	HIGH METER READING	LOW METER READING	ZERO METER READING									
		EXCITER										
A (MOD-1)	Q102, 10- Volt regulator	Q102, CV101, L101, 10-Volt regulator	ICOM, Q101, U101, L101, Q102, CR101, 10-Volt regulator or Channel Selector switch ground.									
B (MOD-2)	Q104, 10- Volt regulator	Q103, L102, L103, CV102, CV103, Q104	Q103, L102, CV102, L103, CV103, CR104, Q104									
C (MULT-1)	Q105, Q106 T101	Q105, Q106	Q105, Q106, T101									
D (MULT-2)	Q107, T104	T101, T102, T103, Q107	T101, T102, T103, Q107, T104									
F (MULT-3)	Q108, T106	T104, T105, Q108	T104, T105, Q108, T106									
G (AMPL-1)	Q109, C146, R144	T106, T107, T108, Q109, L108	T106, T107, T108, Q109, L104, L107									
	P	OWER AMPLIFIER										
"D" (AMPL-1 DRIVE)		Low Output from Exciter	No output from Exciter, CR201									
"C" (AMPL-1 CONTROL VOLT- AGE)	Q217	Q217	No Exciter output, Q217, Q211, CR201									
"F" (DRIVER CURRENT)	Q205	Q205, Low Output from Q204	Q205, Q204, Check Pos. D & C									
"G" (PA CURRENT)	Q206, Q207 Q208, Q209	Q204, Q205, Q206—Q209	Q204, Q205, Q206-Q209 ANTENNA SWITCH K201									

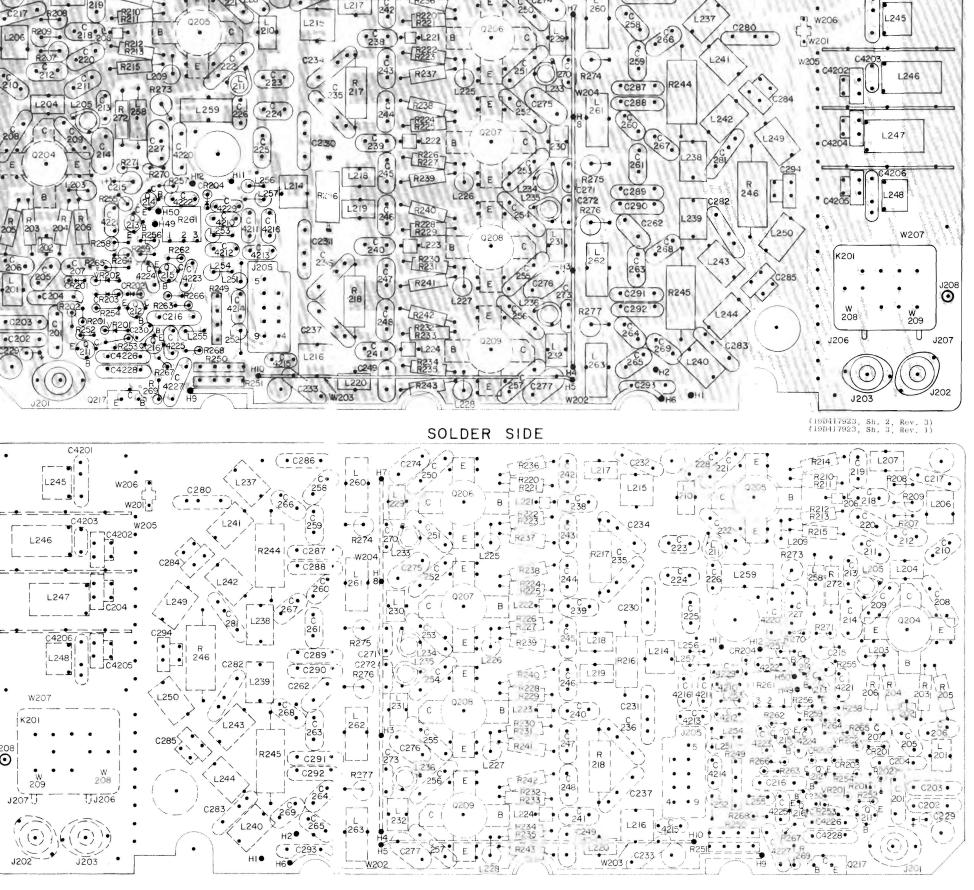


TROUBLESHOOTING PROCEDURE

25-50 MHz, 100-WATT TRANSMITTER







PA BOARD

COMPONENT SIDE

OUTLINE DIAGRAM

25-50 MHz, 100-WATT TRANSMITTER

25-50 MHz EXCITER

SYMBOL GE PART NO. DESCRIPTION 19D416659G2 2 FREQ 30-36 MHz (L 19D416659G3 2 FREQ 36-42 MHz (M 19D416659G4 2 FREQ 42-50 MHz (H 19D416659G8 8 FREQ 42-50 MHz (H) 19A116655P19 ramic disc: 1000 pf ±20%, 1000 VDCW; sim to RMC Type JF Discap. mic disc: 470 pf ±20%, 1000 VDCW; sim to 19A116655P19 ramic disc: 1000 pf ±20%, 1000 VDCW; sim to amic disc: 330 pf ±20%, 1000 VDCW; sim to MC Type JF Discap. 9A116655P21 eramic disc: 2700 pf ±20%, 1000 VDCW; sim to 19All6080Pl05 Polyester: 0.047 µf ±10%, 50 VDCW. 19A116655P19 eramic disc: 1000 pf ±20%, 1000 VDCW; sim to 112LL Silver mica: $680 \text{ pf } \pm 10\%$, 500 VDCW; sim to Electro Motive Type DM-20. 4029003P104 493367P1000K ectro Motive Type DM-20. 493367P1000K eramic disc: 2700 pf $\pm 20\%$, 1000 VDCW; sim to 9A116655P21 RMC Type JF Discap. A116080P105 olyester: 0.047 µf ±10%, 50 VDCW. 5496267P9 Tantalum: 3.3 µf ±20%, 15 VDCW; sim to Sprague 16080P105 olyester: 0.047 µf ±10%, 50 VDCw. Mica: 330 pf $\pm 10\%$, 500 VDCW; sim to Electro Motive Type DM-15. 5490008P139 L9A116080P olyester: 0.01 µf ±20%, 50 VDCW. 5496219P262 eramic disc: 91 pf ±5%, 500 VDCW, temp coef C123LL 6219P258 eramic disc: 62 pf ±5%, 500 VDCW, temp coef eramic disc: 56 pf ±5%, 500 VDCW, temp coef C123M 5496219P257 ramic disc: 43 pf ±5%, 500 VDCW, temp coef C123H henolic: 1.5 pf ±5%, 500 VDCW. C124LL 5491601P123 5491601P120 henolic: 1.0 pf ±5%, 500 VDCW henolic: 1.0 pf ±5%, 500 VDCW. C124M 5491601P120 5491601P119 enolic: 0.82 pf ±5%, 500 VDCW. eramic disc: 91 pf ±5%, 500 VDCW, temp coef 80 PPM. 5496219P262 C125LL 496219P258 eramic disc: 62 pf ±5%, 500 VDCW, temp coef eramic disc: 56 pf ±5%, 500 VDCW, temp coef C125M 5496219P257 ramic disc: 43 pf ±5%, 500 VDCW, temp coef 5496219P254

*COMPONENTS ADDED. DELETED OR CHANGED BY PRODUCTION CHANGES

GE PART NO. DESCRIPTION SYMBOL C126LL 491601P124 henolic: 1.8 pf $\pm 5\%$, 500 VDCw. C126L 5491601P124 Phenolic: 1.8 pf ±5%, 500 VDCW C126M 491601P122 Phenolic: 1.2 pf $\pm 5\%$, 500 VDCW. C126H 5491601P122 Phenolic: 1.2 pf ±5%, 500 VDCW. C1.27LL 496219P262 ramic disc: 91 pf ±5%, 500 VDCW, temp coef 5496219P258 ramic disc: 62 pf ±5%, 500 VDCW, temp coef C127M 5496219P257 camic disc: 56 pf ±5%, 500 VDCW, temp coef C127H 5496219P254 ramic disc: 43 pf ±5%, 500 VDCW, temp coef A116080P1 yester: 0.01 µf ±20%, 50 VDCW. C129LL* Ceramic disc: 47 pf ±5%, 500 VDCW, temp coef -80 PPM. Deleted by REV F. 5496219P255 C129L* 5496219P251 ramic disc: 22 pf ±5%, 500 VDCW, temp coef 5496219P247 C129M* 80 PPM. Deleted by REV F. Ceramic disc: 15 pf $\pm 5\%$, 500 VDCW, temp coef -80 PPM. Deleted by REV F. C130LL 5491601P113 nenolic: 0.47 pf ±5%, 500 VDCW. C130L 5491601P110 henolic: 0.36 pf ±5%, 500 VDCW. 5491601P109 henolic: 0.33 pf ±5%, 500 VDCW. C130M* n REV F & earlier: 5491601P107 Phenolic: 0.27 pf ±5%, 500 VDCW. 5491601P107 C130H* Phenolic: 0.27 pf ±5%, 500 VDCW. In REV F and earlier: 5491601P105 enolic: 0.22 pf ±5%, 500 VDCW. amic disc: 47 pf ±5%, 500 VDCW, temp coef 5496219P255 amic disc: 33 pf ±5%, 500 VDCW, temp coef 5496219P25 5496219P247 C131M amic disc: 22 pf ±5%, 500 VDCW, temp coef C131H 5496219P244 amic disc: 15 pf ±5%, 500 VDCW, temp coef Polyester: 0.01 μ f $\pm 20\%$, 50 VDCW. 19A116080P Cl34LL 5496219P243 ramic disc: 13 pf ±5%, 500 VDCW, temp coef 5496219P240 ramic disc: 9.0 pf ±0.25 pf, 500 VDCW, temp C134M 5496219P242 amic disc: 12 pf ±5%, 500 VDCW, temp coef 5496219P238 ramic disc: 7.0 pf ±0.25 pf, 500 VDCW, temp Phenolic: 0.68 pf ±5%, 500 VDCW. C135LL 5491601Pl17 C135L 5491601P114 nolic: 0.51 pf ±5%, 500 VDCW. C135M enolic: 0.56 pf ±5%, 500 VDCW. 5491601P113 Phenolic: 0.47 pf ±5%, 500 VDCW. C136LL 5496219P243 ramic disc: 13 pf ±5%, 500 VDCW, temp coef ramic disc: 9.0 pf ±0.25 pf, 500 VDCW, temp 5496219P240 mic disc: 12 pf ±5%, 500 VDCW, temp coef C136M ramic disc: 7.0 pf ±0.25 pf, 500 VDCW, temp C136H 5496219P238 5491601P114 Phenolic: 0.51 pf ±5%, 500 VDCW. C137LL enolic: 0.51 pf ±5%, 500 VDCW. 5491601P114 nolic: 0.39 pf ±5%, 500 VDCW. C137M 491601P111 Phenolic: 0.39 pf ±5%, 500 VDCW. C137H 5491601P111

DESCRIPTION GE PART NO. SYMBOL ramic disc: 13 pf ±5%, 500 VDCW, temp coef C138LL 5496219P243 C138L eramic disc: 9.0 pf ±0.25 pf, 500 VDCW, temp 5496219P240 C138M 5496219P242 ramic disc: 12 pf ±5%, 500 VDCW, temp coef C138H 5496219P238 eramic disc: 7.0 pf ±0.25 pf, 500 VDCW. C139 19A116080Pl07 19A116655P19 eramic disc: 1000 pf ±20%, 1000 VDCW; sim to ilver mica: 100 pf ±10%, 500 VDCW; sim to lectro Motive Type DM-15. C141LL 5490008P125 ver mica: 82 pf ±10%, 500 VDCW; sim to C141L lver mica: 68 pf ±10%, 500 VDCW; sim to ectro Motive Type DM-15. C141M 5490008P123 ilver mica: 100 pf ±10%, 500 VDCW; sim to lectro Motive Type DM-15. 5490008P127 C141H 1ver mica: 100 pf ±50%, 50 VDCW; sim to C142LL 5490008P27 lectro Motive Type DM-15. C142L 5490008P25 ilver mica: 82 pf ±5%, 500 VDCW; sim to C142M 5490008P25 ectro Motive Type DM-15. silver mica: 75 pf ±5%, 500 VDCW; sim to lectro Motive Type DM-15. 5490008P24 C142H C143 eramic disc: 330 pf ±20%, 1000 VDCW; sim to C144 5494481 P105 Olyester: 0.01 µf ±20%, 50 VDCW. 19A116080Pl eramic disc: 7.0 pf ±0.25 pf, 500 VDCW, temp 5496219P238 pef -80 PPM. Added by REV B. C146LL* Ceramic: 12 pf, ±5%, 0 PPM. Deleted by REV E C146L* 19A116656P12J8 eramic: 13 pf, ±5%, 0 PPM. Deleted by REV B. C146M* 19Al16656P12J8 19A116080Pl07 Polyester: 0.1 µf ±20%, 50 VDCW. eramic disc: 330 pf ±20%, 1000 VDCW; sim to C148 Tantalum: 22 μf ±20%, 15 VDCW; sim to Sprague 5496267P10 entalum: 15 μ f $\pm 20\%$, 20 VDCW; sim to Sprague pe 1500. Ceramic disc: 330 pf ±20%, 1000 VDCW; sim to 5494481P105 Polyester: 0.01 µf ±20%, 50 VDCW. 19Al16080Pl 19A116867Pl C156* Polyester: 0.01 uf ±20%, 50 VDCW, Added by C157* thru C163* 19A116080Pl - - - - - DIODES AND RECTIFIERS - - - -19A115250Pl 5495769P12 Silicon, capacitive. ---- JACKS AND RECEPTACLES -----Connector, receptacles; sim to Cinch 14H11613. 19A130924G1 19B219374G1 Contact, electrical: sim to Malco XO-2864. 194116651Pl

DESCRIPTION SYMBOL | GE PART NO 9D416635G9 9D416635G17 L101M 9D416635G 9D416635G18 L101H L102LL 9D416635G9 D416635G17 L102M 9D416635G 9D416635G18 D416635G9 9D416635G17 L103M D416635G L103H 9D416635G18 488079P9 hoke, RF: $2.70 \mu h \pm 10\%$, 1.20 ohms DC res max; Choke, RF: 2.20 µh ±10%, 1.00 ohms DC res max; sim to Jeffers 4411-12K. 488079P8 Choke, RF: 1.50 μh ±10%, 0.50 ohms DC res max; sim to Jeffers 4411-10K. L104 M 488079P7

Choke, RF: 1.50 µh ±10%, 0.50 ohms DC res max;

Choke, RF: $0.68 \mu h \pm 10\%$, 0.15 ohms DC res max;

Choke, RF: 0.47 μ h $\pm 10\%$, 0.09 ohms DC res max;

Choke, RF: 0.33 μ h $\pm 10\%$, 0.07 ohms DC res max; sim to Jeffers 4411-3K.

hoke, RF: $10.0 \mu h \pm 10\%$, 0.60 ohms DC res max;

Choke, RF: 39.0 µh ±10%, 2.00 ohms DC res max;

- - - - - - - TRANSISTORS - - - - - -

mposition: 560 ohms $\pm 10\%$, 1/2 w.

mposition: 39K ohms $\pm 10\%$, 1/2 w.

omposition: 470 ohms ±5%, 1/2 w.

omposition: 68 ohms $\pm 10\%$, 1/2 w.

omposition: 220 ohms ±10%, 1/2 w.

omposition: 6.8K ohms ±5%, 1/4 w

R126*

R130

R132

R133

R134

R135

R136

R137

R138

R139

R140

R141

R142

R143LL

R143L

R143M

R143H

R144LL

R144L

R144M

R144H

R145

R146

R151

R152

19B209358P106

3R77P750J

3R77P681K

3R77P332K

3R77P511J

3R77P561K

3R77P102K

3R77P330K

3R77P181K

3R77P121K

3R77P220K

3R77P680K

3R77P220K

3R77P101K

3R77P820K

3R77P820K

3R77P150K

3R77P150K

3R77P100K

3R77P100K

3R77P683K

3R77P102K

3R77P100K

3R77P102K

sim to Jeffers 4411-10K.

sim to Jeffers 4411-8K.

sim to Jeffers 4411-4K.

sim to Jeffers 4422-11K.

ontact strip: 8 pins.

ontact strip: 9 pins.

In REV C and earlier:

icon, NPN; sim to Type 2N3904.

Silicon, NPN.

ilicon, NPN

licon, NPN.

icon, NPN.

icon, NPN.

n REV C and earlier:

arlier than REV A:

488079P7

488079P5

488079P4

488079P16

7488079P50

19B219594P3

9A115330P1

19A115330Pl

19A115328P1

9A115328P1

A115329P2

3R77P561K

3R152P682J

R77P393K

3R77P471J

3R77P680K

3R77P221K

R102*

L105LL

SYMBOL GE PART NO DESCRIPTION R106 3R77P102K Composition: 1K ohms ±10%, 1/2 w. R107 3R77P153K Composition: 15K ohms ±180%, 1/2 w. Composition: 470K ohms ±10%, 1/2 w. R108 3R77P474K R109 Composition: 100K ohms ±10%, 1/2 w R110 Composition: 22K ohms ±10%, 1/2 w. 3R77P223K Composition: 75 ohms ±5%, 1/2 w. R112 3R77P681K Composition: 680 ohms ±1/0%, 1/2 w. R113 3R77P332K omposition: 3.3K ohms ±10%, 1/2 w. R114 Composition: 510 ohms ±5% 1/2 w. R115 3R77P473K Composition: 47K ohms ±10%, 1/2 w. R116 Composition: 560 ohms $\pm 10\%$, 1/2 w. R117 3R77P821K Composition: 820 ohms ±1:0%, 1/2 w. R118 3R77P222K omposition: 2.2K ohms ±40%, 1/2 w 3R77P681K Composition: 680 ohms ±1:0% 1/2 w Composition: 510 ohms ±51%, 1/2 w. 3R77P511J Composition: 22K ohms ±1.0%, 1/2 w. 3R77P153K Composition: 15K ohms ±10%, 1/2 w. R124 3R77P223K Composition: 22K ohms ±1:09, 1/2 w. hoke, RF: 1.00 μ h $\pm 10\%$, 0.30 ohms DC res max; R125 3R77P102K Composition: 1K ohms ±10%, 1/2 w.

Composition: 430 ohms ±5%, 1/2 w.

Composition: 390 ohms ±10%, 1/2 w.

ariable, carbon film: approx 2K to 50K ohms: 10%, 0.25 w; sim to CTS Type X-201.

10%, 0.25 w; sim to CTS Type X-

Composition: 75 ohms ±5%, 1/2 w.

Composition: 680 ohms ±10%, 1/2 w.

Composition: 3.3K ohms ±310% 1/2 w

Composition: 510 ohms ±5%, 1/2 w.

Composition: 47K ohms ±10%, 1/2 w.

Composition: 560 ohms ±10%, 1/2 w.

omposition: 22K ohms ±10%, 1/2 w.

Composition: 1K ohms ±10%, 1/2 w.

Composition: 33 ohms ±10%, 1/2 w.

Composition: 180 ohms ±1.0%, 1/2 w.

Composition: 120 ohms ±10%, 1/2 w.

omposition: 22 ohms ±10%, 1/2 w.

Composition: 68 ohms ±10%, 1/2 w.

Composition: 22 ohms ±10%, 1/2 w.

Composition: 100 ohms ±10%, 1/2 w.

Composition: 100 ohms ±10%, 1/2 w.

Composition: 82 ohms ±10%, 1/2 w.

Composition: 82 ohms ±10%, 1/2 w.

Composition: 15 ohms ±10%, 1/2 w.

Composition: 10 ohms ±10%, 1/2 w.

Composition: 10 ohms ±10%, 1/2 w.

Composition: 33K ohms ±10%, 1/2 w.

Composition: 68K ohms ±1:0%, 1/2 w.

Composition: 33K ohms ±10%, 1/2 w.

Composition: 1K ohms ±10%, 1/2 w.

Composition: 10 ohms ±10%, 1/2 w.

Composition: 1K ohms ±10%, 1/2 w.

In REV D and earlier:

SYMBOL | GE PART NO. DESCRIPTION SYMBOL | GE PART NO. TIOILL 9D416635G10 493185P13 uning slug. T101L 19D416635G10 5493185P13 uning slug. T101M 19D416635G2 Coil, Includes 493185P13 uning slug. 19D416635G2 T101H Coil. Includes 5493185P13 Tuning slug. T102LL 9D416635G11 Coil. Includes 5493185P13 uning slug. 9D416635G11 oil. Includes 5493185P13 Tuning slug. T102M 19D416635G3 5493185P13 Tuning slug. T102H 19D416635G3 Coil. Includes 493185P13 ning slug. 19D416635G12 Coil. Includes T103LL 5493185P13 uning slug. T103L 19D416635G12 oil. Includes 5493185P13 Tuning slug. T103M 9D416635G4 oil. Includes 5493185P13 Tuning slug. T103H 19D416635G4 5493185P13 Tuning slug. T104LL* 19D416635G19 n REV E and earlier 19D416635G13 oil. Includes: 5493185013 ming slug. T104L* 19D416635G20 In REV E and earlier 19D416635G13 493185P13 ining slug. T104M* 19D416635G21 In REV E and earlier: 19D416635G5 oil. Includes 5493185P13 ining slug. 19D416635G2 In REV E and earlier

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oil. Includes

19D416635G5

5493185P13

19D416635G13

493185P13

19D416635G13

5493185P13

19D416635G5

5493185P13

19D416635G5

5493185P13

19D416635G14

5493185P13

19D416635G14

5493185P13

19D416635G6

5493185P13

19D416635G6

5493185P13

T105LL

T105L

T105M

T106LL

T106L

T106M

T106H

T107LL 19D416635G15 il. Includes: 5493185P13 T107L 19D416635G15 oil, Includes: 5493185P13 ming slug. T107M 9D416635G7 oil. Includes: 5493185P13 uning slug. T107H 9D416635G7 oil. Includes: 5493185P13 ning slug. T108LL 19D416635G16 il. Includes: 493185P13 uning slug. T108L 9D416635G16 oil. Includes: 5493185P13 ning slug. T108M 9D416635G8 oil. Includes: 5493185P13 ining slug. T108H 9D416635G8 oil, Includes: 493185P13 uning slug - - - - - INTEGRATED CIRCUITS - - - - -19A116842P1 Frequency Divider: sim to Texas Instrument Type 19D416542G2 VR101 4036887P56 Silicon, Zener

19A116779P1

19A129393G13

19A129393G16

19A121252P1

4029006P3

DESCRIPTION

OTE: When reordering, specify quantity.

Contact, electrical: sim to Molex 08-54-0404.

---- OSCILLATORS -----

NOTE: When reordering specify ICOM Frequency. ICOM Freq = (Operating Freq)

Externally Compensated: 5 PPM, 25-50 MHz.

Can. (Used with T101-T108 and L101-L103).

Insulator, washer: nylon, (Used with Q109).

Clip, compression: 0.375 x 0.19 x .02 inches, sim to Tinnerman Products Inc. C5426-014-24. (Used with Q109).

---- MISCELLANEOUS -----

Compensated: 2 PPM, 25-50 MHz

Heat sink. (Used with Q109)

LBI4898

PRODUCTION CHANGES

are identified by a "Revision Letter", which is stamped after the model number of the unit. The revision stamped on the unit includes all pre-

REV. A - D: - Exciter Board 19D416659G1-8.
Incorporated in initial shipment

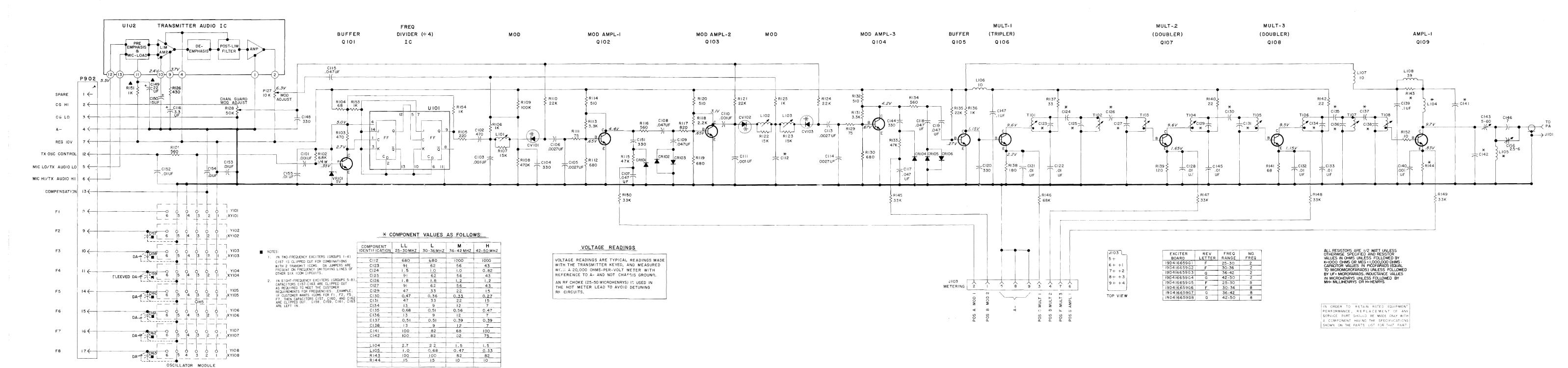
- To eliminate possible shorting of shield to wire runs on printed wire board. Changed Tl04LL, Tl04L, Tl04M and Tl04H. Deleted shield (19B219619P1), Cl29LL, C129L, C129M and C129H.

Exciter Board 19D416659G4&8 REV. G - To improve multi-frequency spread performance in cold

REV. G

- Exciter Board 19D416659G3, 7

To improve operation, Changed C130.



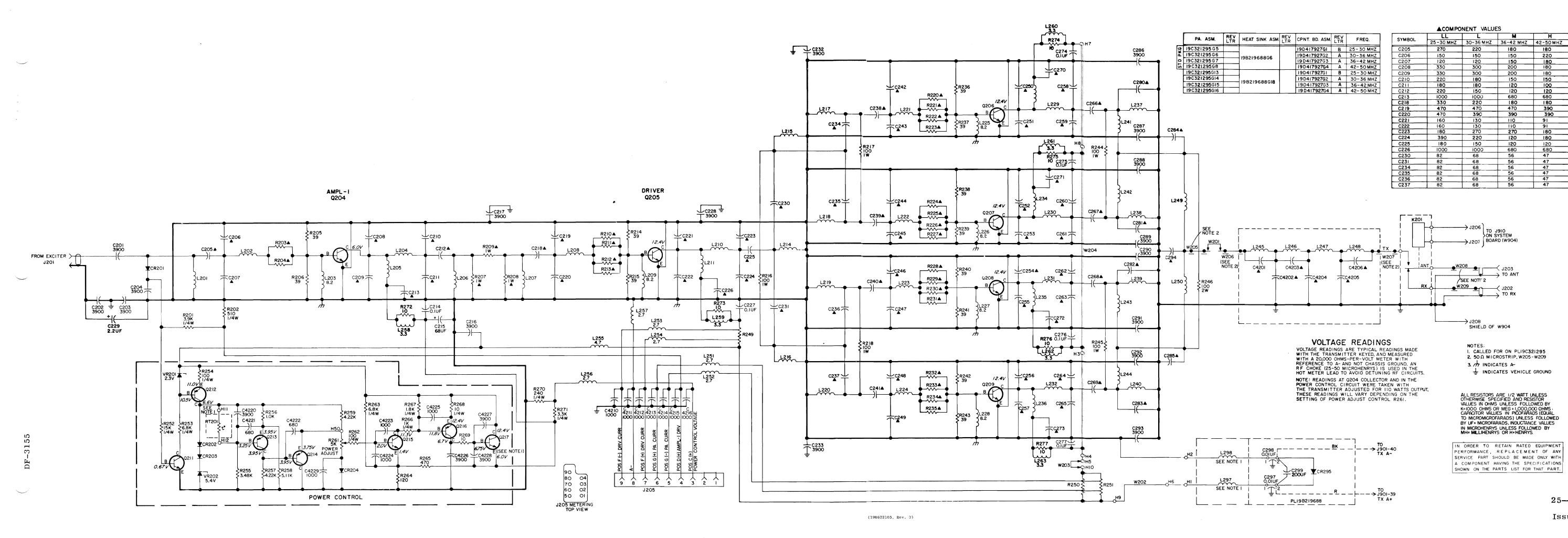
(19R621827, Rev. 16)

SCHEMATIC DIAGRAM

25-50 MHz, EXCITER BOARD 19D416659G1-G8

14

A THESE COMPONENTS NOT PRESENT ON 2ND EXCITER IN WIDE SPACE XMTR COMBINATIONS.



▲COMPONENT VALUES

SCHEMATIC DIAGRAM

25-50 MHz, 100-WATT POWER AMPLIFIER

PARTS LIST LBI-4899A

25-50 MHz, 100 WATT POWER AMPLIFIER 19C321295G5-G8 19C321295G13-G16

SYMBOL	GE PART NO.	DESCRIPTION
		19C321295G5, Gl3 25-30 MHz (LL) 19C321295G6, Gl4 30-36 MHz (L) 19C321295G7, Gl5 36-42 MHz (M) 19C321295G8, Gl6 42-50 MHz (H)
L297	19B219997Pl	Coil.
L298	19B219997P2	Coil.
Q204	19A116965P1	TRANSISTORS
Q205 thru Q209	19A134104P1	Silicon, NPN.
Q217	19A116742P1	Silicon, NPN.
RT201	19A129379Gl	Thermistor.
		POWER AMPLIFIER BOARD 19D417927G1 25-30 MHz (LL) 19D417927G2 30-36 MHz (L) 19D417927G3 36-42 MHz (M) 19D417927G4 42-50 MHz (H)
C201 thru C204	19A116655P23	Ceramic disc: 3900 pf ±20%, 1000 VDCW; sim
C205LL	7489162P37C	Silver mica: 270 pf ±5%, 500 VDCW; sim to Electro Motive Type DM-15.
C205L	7489162P35C	Silver mica: 220 pf ±5%, 500 VDCW; sim to Electro Motive Type DM-15.
C205M and C205H	7489162P33C	Silver mica: 180 pf ±5%, 500 VDCW; sim to Electro Motive Type DM-15.
C206LL	7489162P31C	Silver mica: 150 pf ±5%, 500 VDCW; sim to Electro Motive Type DM-15.
C206L	7489162P31C	Silver mica: 150 pf ±5%, 500 VDCW; sim to Electro Motive Type DM-15.
C206M	7489162P31C	Silver mica: 150 pf ±5%, 500 VDCW; sim to Electro Motive Type DM-15.
C206H	7489162P35C	Silver mica: 220 pf ±5%, 500 VDCW; sim to Electro Motive Type DM-15.
C207LL and C207L	7489162P29C	Silver mica: 120 pf ±5%, 500 VDCW; sim to Electro Motive Type DM-15.
C207M	7489162P31C	Silver mica: 150 pf ±5%, 500 VDCW; sim to Electro Motive Type DM-15.
C207H	7489162P33C	Silver mica: 180 pf $\pm 5\%$, 500 VDCW; sim to Electro Motive Type DM-15.
C208LL	19A116656P330J15	Ceramic disc: 330 pf ±5%, 500 VDCW, temp of -1500 PPM.
C208L	19A116656P300J15	Ceramic disc: 300 pf ±5%, 500 VDCW, temp c -1500 PPM.
C208M	19A116656P200J4	Ceramic disc: 200 pf ±5%, 500 VDCW, temp c -470 PPM.
С208Н	19A116656P180J4	Ceramic disc: 180 pf ±5%, 500 VDCW, temp c -470 PPM.
C209LL	19All6656P330J15	
C209L	19Al16656P300J15	
C209M	19A116656P200 J 4	Ceramic disc: 200 pf ±5%, 500 VDCW, temp c -470 PPM.
С209Н	19A116656P180J4	Ceramic disc: 180 pf $\pm 5\%$, 500 VDCW, temp c -470 PPM.

חח	CE DADT NO	DESCRIPTION	SYMBOL	GE PART NO.	DESCRIPTION
BOL	GE PART NO.	DESCRIPTION	CIMBUL	GE FART NO.	5200m 1.30
10LL	7489162P35C	Silver mica: 220 pf ±5%, 500 VDCW; sim to Electro Motive Type DM-15.	C223L and	7489162P37C	Silver mica: 270 pf ±5%, 500 VDCW; sim to Electro Motive Type DM-15.
10L	7489162P33C	Silver mica: 180 pf $\pm 5\%$, 500 VDCW; sim to Electro Motive Type DM-15.	C223M C223H	7489162 P3 3C	Silver mica: 180 pf ±5%, 500 VDCW; sim to
10M d 10H	7489162P31C	Silver mica: 150 pf ±5%, 500 VDCW; sim to Electro Motive Type DM-15.	C224LL	7489162P41C	Electro Motive Type DM-15. Silver mica: 390 pf ±5%, 500 VDCW; sim to
11LL	7489162P33C	Silver mica: 180 pf ±5%, 500 VDCW; sim to Electro Motive Type DM-15.	C224L	7489162P35C	Electro Motive Type DM-15. Silver mica: 220 pf ±5%, 500 VDCW; sin to
llL llm	7489162P29C		C224M	7489162P29C	Electro Motive Type DM-15. Silver mica: 120 pf $\pm 5\%$, 500 VDCW; sin to
11M	7489162P29C	Silver mica: 120 pf ±5%, 500 VDCW; sim to Electro Motive Type DM-15.	С224Н	7489162P33C	Electro Motive Type DM-15. Silver mica: 180 pf ±5%, 500 VDCW; sin to
		Silver mica: 100 pf ±5%, 500 VDCW; sim to Electro Motive Type DM-15.	C225LL	7489162P33C	Electro Motive Type DM-15. Silver mica: 180 pf ±5%, 500 VDCW; sim to
12LL	7489162P35C	Silver mica: 220 pf ±5%, 500 VDCW; sim to Electro Motive Type DM-15.	C225L	7489162P31C	Electro Motive Type DM-15. Silver mica: 150 pf ±5%, 500 VDCW; sin to
12L	7489162P31C	Silver mica: 150 pf ±5%, 500 VDCW; sim to Electro Motive Type DM-15.	C225M	7489162P29C	Electro Motive Type DM-15. Silver mica: 120 pf ±5%, 500 VDCW; sin to
1 2M 1 1 2H	7489162 P2 9C	Silver mica: 120 pf ±5%, 500 VDCW; sim to Electro Motive Type DM-15.	and C225H	11001001000	Electro Motive Type DM-15.
i3L i i3LL	19A116655P19	Ceramic disc: 1000 pf ±20%, 1000 VDCW; sim to RMC Type JF Discap.	C226LL and C226L	19A116655P19	Ceramic disc: 1000 pf ±20%, 1000 VDCW, sim to RMC Type JF Discap.
13M 1 13H	19A116655P17	Ceramic disc: 680 pf ±20%, 1000 VDCW; sim to RMC Type JF Discap.	C226M and C226H	19All6655P17	Ceramic disc: 680 pf ±20%, 1000 VDCW; sim to RMC Type JF Discap.
14	19A116966P107	Metallized polyester: 0.1 μf ±10%, 50 VDCW.	C227 C228	19A116966P107 19A116655P23	Metallized polyester: 0.1 µf ±10%, 50 VDCW. Ceramic disc: 3900 pf ±20%, 1000 VDCW;
L5	5496267P11	Tantalum: 68 µf ±20%, 15 VDCW; sim to Sprague Type 150D.	C229	5496267P13	sim to RMC Type JF Discap. Tantalum: 2.2 µf ±20%, 20 VDCW; sim to Sprag
16 i 17	19A116655P23	Ceramic disc: 3900 pf ±20%, 1000 VDCW; sim to RMC Type JF Discap.	C230LL	19A116656P82J0	Type 150D, Ceramic disc: 82 pf ±5%, 500 VDCW, temp coef
18LL	7489162P39C	Silver mica: 330 pf ±5%, 500 VDCW; sim to Electro Motive Type DM-15.	C230L	19A116656P68J0	O PPM. Ceramic disc: 68 pf ±5%, 500 VDCW, temp coef
18L	7489162P35C	Silver mica: 220 pf ±5%, 500 VDCW; sim to Electro Motive Type DM-15.	C230M	19A116656P56J0	0 PPM. Ceramic disc: 56 pf ±5%, 500 VDCW, temp coef
1.8M	7489162P33C	Silver mica: 180 pf ±5%, 500 VDCW; sim to Electro Motive Type DM-15.	С230Н	19A116656P47J0	O PPM. Ceramic disc: 47 pf ±5%, 500 VDCW, emp coef
9LL	7489162P43C	Silver mica: 470 pf ±5%, 300 VDCW; sim to	C231LL	19A116656P82J0	O PPM. Ceramic disc: 82 pf ±5%, 500 VDCW, :emp coef
19L	7489162P43C	Electro Motive Type DM-15. Silver mica: 470 pf ±5%, 300 VDCW; sim to	C231L	19A116656P68J0	O PPM. Ceramic disc: 68 pf ±5%, 500 VDCW, temp coef
.9M	7489162P43C	Electro Motive Type DM-15. Silver mica: 470 pf ±5%, 300 VDCW; sim to	C231M	19Al16656P56J0	O PPM. Ceramic disc: 56 pf ±5%, 500 VDCW, temp coef
.9н	7489162P41C	Electro Motive Type DM-15. Silver mica: 390 pf ±5%, 500 VDCW; sim to	С231Н	19A116656P47J0	0 PPM. Ceramic disc: 47 pf ±5%, 500 VDCW, temp coef
OLL	7489162P 43 C	Electro Motive Type DM-15. Silver mica: 470 pf ±5%, 300 VDCW; sim to	C232	19A116655P23	0 PPM. Ceramic disc: 3900 pf ±20%, 1000 VDCW
or [7489162P41C	Electro Motive Type DM-15. Silver mica: 390 pf ±5%, 500 VDCW; sim to	and C233	13/11/00/01/20	sim to RMC Type JF Discap.
eom l	7489162P41C	Electro Motive Type DM-15. Silver mica: 390 pf ±5%, 500 VDCW; sim to	C234LL	19A116656P82J0	Ceramic disc: 82 pf $\pm 5\%$, 500 VDCW, temp coef 0 PPM.
юн	7489162P41C	Electro Motive Type DM-15. Silver mica: 390 pf ±5%, 500 VDCW; sim to	C234L	19A116656P68J0	Ceramic disc: 68 pf ±5%, 500 VDCW, temp coef 0 PPM.
PILL	19A116656P160J3	Electro Motive Type DM-15. Ceramic disc: 160 pf ±5%, 500 VDCW, temp coef	C234M	19A116656P56J0	Ceramic disc: 56 pf ±5%, 500 VDCW, temp coef 0 PPM.
21L	19A116656P130J	-330 PPM. Ceramic disc: 130 pf ±5%, 500 VDCW, temp coef	С234Н	19Al16656P47J0	Ceramic disc: 47 pf ±5%, 500 VDCW, temp coef 0 PPM.
21M	19Al16656Pl10J8	-150 PPM. Ceramic disc: 110 pf ±5%, 500 VDCW, temp coef	C235LL	19A116656P82J0	Ceramic disc: 82 pf $\pm 5\%$, 500 VDCW, temp coef 0 PPM.
21н	19A116656P91J0	-80 PPM. Ceramic disc: 91 pf ±5%, 500 VDCW, temp coef	C235L	19A116656P68J0	Ceramic disc: 68 pf ±5%, 500 VDCW, temp coef 0 PPM.
22LL	19A116656P160J3	0 PPM. Ceramic disc: 160 pf ±5%, 500 VDCW, temp coef	C235M	19A116656P56J0	Ceramic disc: 56 pf $\pm 5\%$, 500 VDCW, temp coef 0 PPM.
22L	19A116656P130J1	-330 PPM. Ceramic disc: 130 pf ±5%, 500 VDCW, temp coef	С235Н	19A116656P47J0	Ceramic disc: 47 pf $\pm 5\%$, 500 VDCW, temp coef 0 PPM.
22M	19Al16656P110J8	-150 PPM. Ceramic disc: 110 pf ±5%, 500 VDCW, temp coef	C236LL	19A116656P82J0	Ceramic disc: 82 pf ±5%, 500 VDCW, temp coef 0 PPM.
22H	19A116656P91J0	-80 PPM. Ceramic disc: 91 pf ±5%, 500 VDCW, temp coef	C236L	19Al16656P68J0	Ceramic disc: 68 pf ±5%, 500 VDCW, temp coef 0 PPM.
23LL	7489162P33C	O PPM. Silver mica: 180 pf ±5%, 500 VDCW; sim to	C236M	19All6656P56J0	Ceramic disc: 56 pf ±5%, 500 VDCW, temp coef 0 PPM.
.out	(709102P33C	Electro Motive Type DM-15.	С236Н	19A116656P47J0	Ceramic disc: 47 pf ±5%, 500 VDCW, temp coef 0 PPM.

SYMBOL	GE PART NO.	DESCRIPTION	SYMBOL	GE PART NO.	DESCRIPTION
C237LL	19A116656P82J0	Ceramic disc: 82 pf ±5%, 500 VDCW, temp coef 0 PPM.	C248LL and C248L	7489162P43C	Silver mica: 470 pf ±5%, 300 VDCW; sim to Electro Motive Type DM-15.
C 237 L	19A116656P68J0	Ceramic disc: 68 pf ±5%, 500 VDCW, temp coef 0 PPM.	C248E C248M and	7489162P41C	Silver mica: 390 pf ±5%, 500 VDCW; sim to Electro Motive Type DM-15.
C237M	19A116656P56J0	Ceramic disc: 56 pf ±5%, 500 VDCW, temp coef O PPM.	C248H	7489162 P4 3C	Silver mica: 470 pf ±5%, 300 VDCW; sim to
С237Н	19A116656P47J0	Ceramic disc: 47 pf ±5%, 500 VDCW, temp coef 0 PPM.	C249L	7489162P41C	Electro Motive Type DM-15.
C238LL	7489162P39C	Silver mica: 330 pf ±5%, 500 VDCW; sim to Electro Motive Type DM-15.	C249h	7489162P39C	Silver mica: 390 pf ±5%, 500 VDCW; sim to Electro Motive Type DM-15.
C238L	7489162P35C	Silver mica: 220 pf ±5%, 500 VDCW; sim to Electro Motive Type DM-15.	and C249H	7469102P39C	Silver mica: 330 pf ±5%, 500 VDCW; sim to Electro Motive Type DM-15.
C238M and	7489162P33C	Silver mica: 180 pf ±5%, 500 VDCW; sim to Electro Motive Type DM-15.	C250LL	19A116656P160J3	Ceramic disc: 160 pf $\pm 5\%$, 500 VDCW, temp coe-330 PPM.
C238H C239LL	748916 2P39 C	Silver mica: 330 pf $\pm 5\%$, 500 VDCW; sim to	C250L	19Al16656P130J1	Ceramic disc: 130 pf $\pm 5\%,~500$ VDCW, temp coe-150 PPM.
C239L	7489162P35C	Electro Motive Type DM-15. Silver mica: 220 pf ±5%, 500 VDCW; sim to	C250M	19Al16656Pl10J8	Ceramic disc: 110 pf $\pm 5\%,~500$ VDCW, temp coe -80 PPM.
C239M	7489162P33C	Electro Motive Type DM-15. Silver mica: 180 pf ±5%, 500 VDCW; sim to	С250Н	19A116656P91J0	Ceramic disc: 91 pf $\pm 5\%$, 500 VDCW, temp coef 0 PPM.
and C239H		Electro Motive Type DM-15.	C251LL	19A116656P160J3	Ceramic disc: 160 pf $\pm 5\%$, 500 VDCW, temp coe -330 PPM.
C240LL	7489162P39C	Silver mica: 330 pf $\pm 5\%$, 500 VDCW; sim to Electro Motive Type DM-15.	C251L	19A116656P130J1	Ceramic disc: 130 pf ±5%, 500 VDCW, temp coe: -150 PPM.
C240L	7489162P35C	Silver mica: 220 pf ±5%, 500 VDCW; sim to Electro Motive Type DM-15.	C251M	19A116656P110J8	Ceramic disc: 110 pf $\pm 5\%$, 500 VDCW, temp coe-80 PPM.
C240M and C240H	7489162P33C	Silver mica: 180 pf $\pm 5\%$, 500 VDCW; sim to Electro Motive Type DM-15.	С251Н	19A116656P91J0	Ceramic disc: 91 pf ±5%, 500 VDCW, temp coef 0 PPM.
C241LL	7489162P39C	Silver mica: 330 pf ±5%, 500 VDCW; sim to Electro Motive Type DM-15.	C252LL	19All6656Pl60J3	Ceramic disc: 160 pf ±5%, 500 VDCW, temp coe -330 PPM.
C241L	7489162P35C	Silver mica: 220 pf ±5%, 500 VDCW; sim to Electro Motive Type DM-15.	C252L	19A116656Pl30J1	Ceramic disc: 130 pf ±5%, 500 VDCW, temp coe -150 PPM.
C241M and	7489162P33C	Silver mica: 180 pf ±5%, 500 VDCW; sim to Electro Motive Type DM-15.	C252M	19A116656P110J8	Ceramic disc: 110 pf ±5%, 500 VDCW, temp coe -80 PPM.
C241H C242LL	7489162P43C	Silver mica: 470 pf ±5%, 300 VDCW; sim to	С252Н	19A116656P91J0	Ceramic disc: 91 pf ±5%, 500 VDCW, temp coef 0 PPM.
and C242L	14831027430	Electro Motive Type DM-15.	C253LL	19A116656P160J3	Ceramic disc: 160 pf ±5%, 500 VDCW, temp coe -330 PPM.
C242M and C242H	7489162P41C	Silver mica: 390 pf $\pm 5\%$, 500 VDCW; sim to Electro Motive Type DM-15.	C253L	19A116656P130J1	Ceramic disc: 130 pf ±5%, 500 VDCW, temp coe -150 PPM.
C243LL	7489162P43C	Silver mica: 470 pf ±5%, 300 VDCW; sim to Electro Motive Type DM-15.	C253M	19A116656P110J8	Ceramic disc: 110 pf ±5%, 500 VDCW, temp coe -80 PPM.
C243L	7489162P41C	Silver mica: 390 pf ±5%, 500 VDCW; sim to Electro Motive Type DM-15.	С253Н	19A116656P91J0	Ceramic disc: 91 pf ±5%, 500 VDCW, temp coef 0 PPM.
C243M	7489162P39C	Silver mica: 330 pf ±5%, 500 VDCW; sim to Electro Motive Type DM-15.	C254LL	19Al16656P160J3	Ceramic disc: 160 pf ±5%, 500 VDCW, temp coe -330 PPM.
and C243H C244LL	7489162P43C	Silver mica: 470 pf ±5%, 300 VDCW; sim to	C254L	19A116656P130J1	Ceramic disc: 130 pf ±5%, 500 VDCW, temp coe ~150 PPM.
and C244L	7489162P43C	Electro Motive Type DM-15.	C254M	19A116656P110J8	Ceramic disc: 110 pf ±5%, 500 VDCW, temp coe -80 PPM.
C244M and	7489162P41C	Silver mica: 390 pf ±5%, 500 VDCW; sim to Electro Motive Type DM-15.	С254Н	19A116656P91J0	Ceramic disc: 91 pf ±5%, 500 VDCW, temp coef 0 PPM.
C244H C245LL	7489162P43C	Silver mica: 470 pf ±5%, 300 VDCW; sim to	C255LL	19A116656P160J3	Ceramic disc: 160 pf ±5%, 500 VDCW, temp coe -330 PPM.
C245L	7489162P41C	Electro Motive Type DM-15. Silver mica: 390 pf ±5%, 500 VDCW; sim to	C255L	19Al16656Pl30Jl	-330 PPM. Ceramic disc: 130 pf ±5%, 500 VDCW, temp coe -150 PPM.
C245M	7489162P39C	Electro Motive Type DM-15. Silver mica: 330 pf ±5%, 500 VDCW; sim to	C255M	19A116656P110J8	-150 PPM. Ceramic disc: 110 pf ±5%, 500 VDCW, temp coe -80 PPM.
and C245H		Electro Motive Type DM-15.	С255Н	19A116656P91J0	Ceramic disc: 91 pf ±5%, 500 VDCW, temp coef
C246LL and C246L	7489162P43C	Silver mica: 470 pf ±5%, 300 VDCW; sim to Electro Motive Type DM-15.	C256LL	19A116656P160J3	O PPM. Ceramic disc: 160 pf ±5%, 500 VDCW, temp coe
C246M and	7489162P41C	Silver mica: 390 pf ±5%, 500 VDCW; sim to Electro Notive Type DM-15.	C256L	19All6656Pl30Jl	-330 PPM. Ceramic disc: 130 pf ±5%, 500 VDCW, temp coe
C246H C247LL	7489162P43C	Silver mica: 470 pf ±5%, 300 VDCW; sim to	C256M	19A116656P110J8	-150 PPM. Ceramic disc: 110 pf ±5%, 500 VDCW, temp coe
C247L	7489162P41C	Electro Motive Type DM-15. Silver mica: 390 pf_±5%, 500 VDCW; sim to	С256Н	19A116656P91J0	-80 PPM. Ceramic disc: 91 pf ±5%, 500 VDCW, temp coef
C247M	7489162P39C	Electro Motive Type DM-15. Silver mica: 330 pf ±5%, 500 VDCW; sim to	C257LL	19All6656Pl60J3	O PPM. Ceramic disc: 160 pf ±5%, 500 VDCW, temp coe
and C247H		Electro Motive Type DM-15.			-330 PPM.
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SYMBOL	GE PART NO.	DESCRIPTION	SYMBOL	GE PART NO.	DESCRIPTION	SYMBOL	GE PART NO.	DESCRIPTION
1005.51	201110070710011			T4001/00000	513 100 1 157 500 NBON	C285LL	19A116679P240J	Mica: 240 pf ±5%, 250 VDCW.
©257L	19A116656P130J1	Ceramic disc: 130 pf ±5%, 500 VDCW, temp coef -150 PPM.	C268LL and C268L	7489162 P 33C	Silver mica: 180 pf ±5%, 500 VDCW; sim to Electro Motive Type DM-15.	C285L	19A116679P200J	Mica: 200 pf ±5%, 250 VDCW.
©257M	19A116656P110J8	Ceramic disc: 110 pf ±5%, 500 VDCW, temp coef -80 PPM.	C268M and	7489162P29C	Silver mica: 120 pf ±5%, 500 VDCW; sim to Electro Motive Type DM-15.	C285M	19A116679P160J	Mica: 160 pf ±5%, 250 VDCW.
€257H	19A116656P91J0	Ceramic disc: 91 pf ±5%, 500 VDCW, temp coef 0 PPM.	С268Н			C285H C286	19A116679P140J 19A116655P23	Mica: 140 pf ±5%, 250 VDCW. Ceramic disc: 3900 pf ±20%, 1000 VDCW;
©258LL	7489162P41C	Silver mica: 390 pf ±5%, 500 VDCW; sim to Electro Motive Type DM-15.	C269LL and C269L	7489162 P 83C	Silver mica: 180 pf ±5%, 500 VDCW; sim to Electro Motive Type DM-15.	thru C293		sim to RMC Type JF Discap.
©258L and ©258M	7489162P37C	Silver mica: 270 pf ±5%, 500 VDCW; sim to Electro Motive Type DM-15.	C269M and C269H	7489162P29C	Silver mica: 120 pf ±5%, 500 VDCW; sim to Electro Motive Type DM-15.	C294LL C294L	19A116679P160J 19A116679P130J	Mica: 160 pf ±5%, 250 VDCW. Mica: 130 pf ±5%, 250 VDCW.
©258H	19Al16679P200J	Mica: 200 pf ±5%, 250 VDCW.	C270LL	19A116655P19	Ceramic disc: 1000 pf ±20%, 1000 VDCW;	C294M	19A116679P110J	Mica: 110 pf ±5%, 250 VDCW.
and ©259LL			and C270L		sim to RMC Type JF Discap.	C294H C4201LL*	19A116679P91J 19A116656P91J1	Mica: 91 pf ±5%, 250 VDCW. Ceramic disc: 91 pf ±5%, 500 VDCW, temp coef
©259L	7489162P35C	Silver mica: 220 pf ±5%, 500 VDCW; sim to Electro Motive Type DM-15.	C270M and C270H	19A116655P17	Ceramic disc: 680 pf ±20%, 1000 VDCW; sim to RMC Type JF Discap.	C4201ED	194110030F3131	-150 PPM. In REV A and earlier:
©259M	7489162P29C	Silver mica: 120 pf ±5%, 500 VDCW; sim to Electro Motive Type DM-15.	C271LL and	19A116655P19	Ceramic disc: 1000 pf ±20%, 1000 VDCW; sim to RMC Type JF Discap.		19A116656P82J1	Ceramic disc: 82 pf ±5%, 500 VDCW, temp coef -150 PPM.
С259Н	7489162P33C	Silver mica: 180 pf ±5%, 500 VDCW; sim to Electro Motive Type DM-15.	C271L C271M	194116655917	Ceramic disc: 680 pf ±20%, 1000 VDCW;	C4201L	19A116656P68J1	Ceramic disc: 68 pf ±5%, 500 VDCW, temp coef
ଅ260LL	7489162P41C	Silver mica: 390 pf ±5%, 500 VDCW; sim to Electro Motive Type DM-15.	and C271H	10/11/1900/11	sim to RMC Type JF Discap.	C4201M	19Al16656P56J1	-150 PPM. Ceramic disc: 56 pf ±5%, 500 VDCW, temp coef
©260L aund C:260M	7489162P37C	Silver mica: 270 pf ±5%, 500 VDCW; sim to Electro Motive Type DM-15.	C272LL and C272L	19A116655P19	Ceramic disc: 1000 pf ±20%, 1000 VDCW; sim to RMC Type JF Discap.	С4201Н	19A116656P51J1	-150 PPM. Ceramic disc: 51 pf ±5%, 500 VDCW, temp coef -150 PPM.
C:260H aund	7489162P33C	Silver mica: 180 pf ±5%, 500 VDCW; sim to Electro Motive Type DM-15.	C272M and	19A116655P17	Ceramic disc: 680 pf ±20%, 1000 VDCW; sim to RMC Type JF Discap.	C4202LL	19A116679P110J	Mica: 110 pf ±5%, 250 VDCW.
C261LL	# 4001 00 mose		C272H	104116655p10		C4202L	19A116679P91J	Mica: 91 pf ±5%, 250 VDCW.
C:261L	7489162P35C	Silver mica: 220 pf ±5%, 500 VDCW; sim to Electro Motive Type DM-15.	C273LL and C273L	19A116655P19	Ceramic disc: 1000 pf ±20%, 1000 VDCW; sim to RMC Type JF Discap.	C4202M	19A116679P68J	Mica: 68 pf ±5%, 250 VDCW.
C:261M	7489162P29C	Silver mica: 120 pf ±5%, 500 VDCW; sim to Electro Motive Type DM-15.	C273M	19Al16655Pl7	Ceramic disc: 680 pf ±20%, 1000 VDCW;	C4202H C4203LL	19A116679P56J 19A116656P15J1	Mica: 56 pf ±5%, 250 VDCW. Ceramic disc: 15 pf ±5%, 500 VDCW, temp coef
C:261H	7489162P33C	Silver mica: 180 pf ±5%, 500 VDCW; sim to Electro Motive Type DM-15.	and C273H		sim to RMC Type JF Discap.	C4203L	19Al16656pl3Jl	-150 PPM. Ceramic disc: 13 pf ±5%, 500 VDCW, temp coef
C:262LL	7489162P41C	Silver mica: 390 pf ±5%, 500 VDCW; sim to Electro Motive Type DM-15.	C274 thru C277	19A116966P107	Metallized polyester: 0.1 μf ±10%, 50 VDCW.			-150 PPM.
C:262L aind	7489162P37C	Silver mica: 270 pf ±5%, 500 VDCW; sim to Electro Motive Type DM-15.	C280LL	19A116656P82J0	Ceramic disc: 82 pf ±5%, 500 VDCW, temp coef 0 PPM.	C4203M C4203H	19A116656P12J1	Ceramic disc: 12 pf ±5%, 500 VDCW, temp coef -150 PPM. Ceramic disc: 10 pf ±5%, 500 VDCW, temp coef
C:262M C:262H	7489162P33C	Silver mica: 180 pf ±5%, 500 VDCW; sim to	C280L	19A116656P68J0	Ceramic disc: 68 pf ±5%, 500 VDCW, temp coef 0 PPM.		19A116679P140J	-150 PPM. Mica: 140 pf ±5%, 250 VDCW.
a.nd C:263LL		Electro Motive Type DM-15.	C280M	19A116656P56J0	Ceramic disc: 56 pf ±5%, 500 VDCW, temp coef 0 PPM.	C4204LL C4204L	19A116679P110J	Mica: 110 pf ±5%, 250 VDCW.
C:263L	7489162P35C	Silver mica: 220 pf ±5%, 500 VDCW; sim to Electro Motive Type DM-15.	С280Н	19A116656P47J0	Ceramic disc: 47 pf ±5%, 500 VDCW, temp coef	C4204M	19A116679P91J	Mica: 91 pf ±5%, 250 VDCW.
C:263M	7489162P29C	Silver mica: 120 pf ±5%, 500 VDCW; sim to Electro Motive Type DM-15.	C281LL	19A116656P82J0	O PPM. Ceramic disc: 82 pf ±5%, 500 VDCW, temp coef	C4204H C4205LL*	19A116679P82J 19A116656P91J1	Mica: 82 pf ±5%, 250 VDCW. Ceramic disc: 91 pf ±5%, 500 VDCW, temp coef
С:263Н	7489162P33C	Silver mica: 180 pf ±5%, 500 VDCW; sim to Electro Motive Type DM-15.	C281L	19Al16656P68J0	O PPM. Ceramic disc: 68 pf ±5%, 500 VDCW, temp coef	C4203LL*	19411003049101	-150 PPM.
C:264LL	7489162P41C	Silver mica: 390 pf ±5%, 500 VDCW; sim to Electro Motive Type DM-15.	C281M	19Al16656P56J0	O PPM. Ceramic disc: 56 pf ±5%, 500 VDCW, temp coef		19A116656P82J1	In REV A and earlier: Ceramic disc: 82 pf ±5%, 500 VDCW, temp coef
C:264L a:nd	7489162P37C	Silver mica: 270 pf ±5%, 500 VDCW; sim to Electro Motive Type DM-15.	С281Н	19A116656P47J0	O PPM. Ceramic disc: 47 pf ±5%, 500 VDCW, temp coef	C4205L	19A116679P100J	-150 PPM. Mica: 100 pf ±5%, 250 VDCW.
C:264M C:264H	7489162P33C	Silver mica: 180 pf ±5%, 500 VDCW; sim to	C282LL	19A116656782J0	O PPM. Ceramic disc: 82 pf ±5%, 500 VDCW, temp coef	C4205M	19A116679P82J	Mica: 82 pf ±5%, 250 VDCW.
aand C:265LL	74051022330	Electro Motive Type DM-15.			O PPM.	C4205H C4206LL	19A116679P75J 19A116656P82J1	Mica: 75 pf ±5%, 250 VDCW. Ceramic disc: 82 pf ±5%, 500 VDCW, temp coef
C:265L	7489162 P35 C	Silver mica: 220 pf ±5%, 500 VDCW; sim to Electro Motive Type DM-15.	C282L	19A116656768J0	Ceramic disc: 68 pf ±5%, 500 VDCW, temp coef 0 PPM.	C4206L	19A116656P68J1	-150 PPM. Ceramic disc: 68 pf ±5%, 500 VDCW, temp coef
C:265M	7489162P29C	Silver mica: 120 pf ±5%, 500 VDCW; sim to Electro Motive Type DM-15.	C282M	19A116656P56J0	Ceramic disc: 56 pf ±5%, 500 VDCW, temp coef 0 PPM.	C4206M	19A116656P56J1	-150 PPM. Ceramic disc: 56 pf ±5%, 500 VDCW, temp coef
С:265н	7489162P33C	Silver mica: 180 pf ±5%, 500 VDCW; sim to Electro Motive Type DM-15.	С282Н	19A116656P47J0	Ceramic disc: 47 pf ±5%, 500 VDCW, temp coef 0 PPM.		19A116656P51J1	-150 PPM. Ceramic disc: 51 pf ±5%, 500 VDCW, temp coef
C:266LL	7489162P33C	Silver mica: 180 pf ±5%, 500 VDCW; sim to Electro Motive Type DM-15.	C283LL	19A116656P82J0	Ceramic disc: 82 pf ±5%, 500 VDCW, temp coef 0 PPM.	C4206H		-150 PPM.
C:266L	7489162P33C	Silver mica: 180 pf ±5%, 500 VDCW; sim to Electro Motive Type DM-15,	C283L	19A116656P68J0	Ceramic disc: 68 pf ±5%, 500 VDCW, temp coef 0 PPM.	C4210 thru C4216	19A116655P19	Ceramic disc: 1000 pf ±20%, 1000 VDCW; sim to RMC Type JF Discap.
C:266M aand	7489162 P 29C	Silver mica: 120 pf ±5%, 500 VDCW; sim to Electro Motive Type DM-15.	C283M	19A116656P56J0	Ceramic disc: 56 pf ±5%, 500 VDCW, temp coef 0 PPM.	C4220	19Al16655P23	Ceramic disc: 3900 pf $\pm 20\%$, 1000 VDCW; sim to RMC Type JF Discap.
C:266H C:267LL	7489162P33C	Silver mica: 180 pf ±5%, 500 VDCW; sim to	С283Н	19A116656P47J0	Ceramic disc: 47 pf ±5%, 500 VDCW, temp coef O PPM.	C4221 and C4222	19A116655P17	Ceramic disc: 680 pf $\pm 20\%$, 1000 VDCW; sim to RMC Type JF Discap.
a.nd C: 267L		Electro Motive Type DM-15.	C284LL C284L	19A116679P240J 19A116679P200J	Mica: 240 pf ±5%, 250 VDCW. Mica: 200 pf ±5%, 250 VDCW.	C4223	19A116655P19	Ceramic disc: 1000 pf ±20%, 1000 VDCW; sim to RMC Type JF Discap.
C:267M a-nd C:267H	7489162P29C	Silver mica: 120 pf ±5%, 500 VDCW; sim to Electro Motive Type DM-15.	C284M	19A116679P160J	Mica: 160 pf ±5%, 250 VDCW.	thru C4225		
n, og.e			С284Н	19Al16679P140J	Mica: 140 pf ±5%, 250 VDCW.	C4226 thru C4228	19A116655P23	Ceramic disc: $3900 \text{ pf } \pm 20\%$, 1000 VDCW ; sim to RMC Type JF Discap.
						C4229	19A116655P19	Ceramic disc: 1000 pf ±20%, 1000 VDCW; sim to RMC Type JF Discap.
								(Continued on Page 17)
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SYMBOL GE PART NO.	DESCRIPTION	SYMBOL	GE PART NO.	DESCRIPTION	SYMBOL	GE PART NO.	DESCRIPTION	SYMBOL	GE PART NO.	DESCRIPTION	SYMBOL	GE PART NO.		DESCRIPTION	SYMBOL	GE PART NO.	DESCRIPTION	SYMBOL	GE PART NO.	DESCRIPTION
y	DIODES AND RECTIFIERS	L214M	19C320617P18	Coil.	L231L	19C320617P35	Coil.	L245H	19A129360P1	Coil.	R208LL	3R78P681J	Compositi	ion: 680 ohms ±5%, 1 w.	R226L	7147161p34	Composition: 3.9 ohms $\pm 5\%$, $1/2$ w.	R259	19A116278P261	Metal film: 4220 ohms ±2%, 1/2 w.
CR201* 19A116052P2	Silicon.	L214H	19C320617P14	Coil.	L231M	19C320617P12	Coil.	L246LL	19Al29360Pl0	Coil.	R208L	3R78P681J	Compositi	ion: 680 ohms ±5%, 1 w.	R226M	7147161P27	Composition: 2.0 ohms $\pm 5\%$, $1/2$ w.	R261	19A116559P102	Variable, cermet: 5000 ohms ±20%, .5 w; sim to
	Earlier than REV A:	L215LL	19C320617P13	Coil.	L231H	19C320617P17	Coil.	L246L	19Al29360P7	Coil.	R208M	3R78P681J	Compositi	ion: 680 ohms ±5%, 1 w.	R226H	7147161P22	Composition: 1.2 ohms $\pm 5\%$, $1/2$ w.	R262	3R152P101J	CTS Series 360. Composition: 100 ohms ±5%, 1/4 w.
19A115250P1	Silicon.	L215L	19C320617P33	Coil.	L232LL	19C320617P16	Coil.	L246M	19A129360P3	Coil.	R208H	3R78P911J	Compositi	ion: 910 ohms ±5%., 1 w.	R227LL	7147161P39	Composition: 6.8 ohms $\pm 5\%$, $1/2$ w.	R263	3R152P682J	Composition: 6800 ohms $\pm 5\%$, $1/4$ w.
CR202 19A115250P1 thru	Silicon.	L215M	19C320617P34	Coil.	L232L	19C320617P35	Coil.	L246H	19Al29360P2	Coil.		5490205P14		ion: 8.2 ohms ±5%, 1 w.	R227L	7147161P34	Composition: 3.9 ohms $\pm 5\%$, $1/2$ w.	R264	3R77P121J	Composition: 120 ohms ±5%, 1/2 w.
CR204		L215H	19C320617P18	Coil.	L232M	19C320617P12	Coil,	L247LL		Coil.		5490205P14		ion: 8.2 ohms ±5%, 1 w.	R227M	7147161P27	Composition: 2.0 ohms $\pm 5\%$, $1/2$ w.	R265	3R77P471J	Composition: 470 ohms $\pm 5\%$, $1/2$ w.
1201 10411600001	JACKS AND RECEPTACLES	L216LL	19C320617P13	Coil.	L232H	19C320617P17	Coil.	L247L	19A129360P8	Coil.		5490205P14	i	ion: 8.2 ohms ±5%, 1 w.	R227H	7147161P22	Composition: 1.2 ohms ±5%, 1/2 w.	R266	3R152P102J	Composition: 1000 ohms $\pm 5\%$, $1/4$ w.
J201 19A116832P1 thru J203	Receptacle, coaxial: sim to Cinch 14H11613.	L216L	19C320617P33	Coil.	L233LL	19C320618P2	Coil.	L247M		Coil.		5490205P6	ı	ion: 5.6 ohms ±5%, 1 w.	R228LL	7147161P39	Composition: 6.8 ohms ±5%, 1/2 w.	R267	3R152P182J	Composition: 1800 ohms $\pm 5\%$, 1/4 w.
J205 19B219374G1	Connecton: 0 contacts	L216M	19C320617P34	Coil.	L233L and	19C320618P6	Coil.	L247H		Coil.		7147161P39		ion: 6.8 ohms ±5%, 1/2 w.	R228L	7147161P34	Composition: 3.9 ohms ±5%, 1/2 w.	R268	3R152P100J	Composition: 10 ohms ±5%, 1/4 w.
J206 19B219374G1	Connector: 9 contacts. (Part of K201).	L216H	19C320617P18	Coil.	L233M			L248LL		Coil.		7147161P34	1	ion: 3.9 ohms ±5%, 1/2 w.	R228M	7147161P27	Composition: 2.0 ohms ±5%, 1/2 w.	R269	3R77P100J	Composition: 10 ohms ±5%, 1/2 w.
and J 207	(Part of R201).	L217LL	19C320617P15	Coil.	L233H	19C320618P1	Coil.	L248L	19A129360P6	Coil.		7147161P27 7147161P22	ı	ion: 2.0 ohms ±5%, 1/2 w.	R228H R229LL	7147161P22	Composition: 1.2 ohms ±5%, 1/2 w.	R270	3R152P241J	Composition: 240 ohms ±5%, 1/4 w.
J208 4033513P4	Contact, electrical: sim to Bead Chain L93-3.	L217L	19C320617P5	Coil.	L234LL	1	Coil.	L248M		Coil.		7147161P22 7147161P39		ion: 1.2 ohms ±5%, 1/2 w.	R229LL R229L	7147161P39 7147161P34	Composition: 6.8 ohms ±5%, 1/2 w.	R271	3R152P332J	Composition: 3300 ohms ±5%, 1/4 w.
400001014	contact, electricar. Sim to bead thath 195-5.	L217M	19C320617P26	Coil.	L235L and	19C320618P6	Coil.	L248H		Coil.		7147161P39 7147161P34		ion: 6.8 ohms ±5%, 1/2 w.	R229L	7147161P34 7147161P27	Composition: 3.9 ohms ±5%, 1/2 w. Composition: 2.0 ohms ±5%, 1/2 w.	R272	3R77P100J	Composition: 10 ohms ±5%, 1/2 w.
	RELAYS	L217H	19C320617P6	Coil.	L235M			L249LL L249L	19C320617P41 19C320617P42	Coil.	'	7147161P37	l l	ion: 3.9 ohms ±5%, 1/2 w. ion: 2.0 ohms ±5%, 1/2 w.	R229H	7147161P21 7147161P22	Composition: 1.2 ohms ±5%, 1/2 w.	R273 thru	3R78P100K	Composition: 10 ohms ±10%, 1 w.
K201 19A116722P1	Hermetic sealed: 125 ohms ±20%, 1 form C contact, 9.6 to 15.8 VDC (over the temp	L218LL	19C320617P15	Coil.	L235H	19C320618P1	Coil.	L249L L249M	19C320617P42	Coil.		7147161P27	l l	ion: 1.2 ohms ±5%, 1/2 w.	R230LL	7147161P39	Composition: 6.8 ohms ±5%, 1/2 w.	R277		Way Taken, Programment
	range indicated.	L218L	19C320617P5	Coil,	L236LL	19C320618P2	Coil.	L249H	19C320617P43	Coil.		7147161P39	· I	ion: 6.8 ohms ±5%, 1/2 w.	R230L	7147161P34	Composition: 3.9 ohms ±5%, 1/2 w.	VR201	4036887P1	VOLTAGE REGULATORS
	INDUCTORS	L218M	19C320617P26	Coil.	L236L and	19C320618P6	Coil.	L250LL		Coil.		7147161P34	1 .	ion: 3.9 ohms ±5%, 1/2 w.	R230M	7147161P27	Composition: 2.0 ohms ±5%, 1/2 w.		į	Silicon Zener.
L201LL 19C320617P1	Coil.	L218H	19C320617P6	Coil.	L236M			L250L	19C320617P41	Coil.		7147161P27		ion: 2.0 ohms ±5%, 1/2 w.	R230H	7147161P22	Composition: 1.2 ohms ±5%, 1/2 w.	VR202	4036887P5	Silicon, Zener.
L201L 19C320617P23	Coil.	L219LL	19C320617P15	Coil.	L236H	19C320618P1	Coil.		19C320617P42	Coil.		7147161P22	l l	ion: 1.2 ohms ±5%, 1/2 w.	R231LL	7147161P39	Composition: 6.8 ohms ±5%, 1/2 w.			
L201M 19C320617P24	Coil.	L219L	19C320617P5	Coil.	L237LL	19C320617P37	Coil.	L250M				7147161P39	1	ion: 6.8 ohms ±5%, 1/2 w.	R231L	7147161P34	Composition: 3.9 ohms ±5%, 1/2 w.	W201	19A129571P1	Strap.
L201H 19C320617P2	Coil.	L219M	19C320617P26	Coil.	L237L	19C320617P38	Coil.	L250H	19C320617P44	Coil.		7147161P34		ion: 3.9 ohms ±5%, 1/2 w.	R231M	7147161P27	Composition: 2.0 ohms ±5%, 1/2 w.	W202	19B219998P2	Jumper.
L202LL 19C320617P3	Coil.	L219H	19C320617P6	Coil,	L237M	19C320617P39	Coil.	L251 thru	7488079P9	Choke, RF: 2.70 μh $\pm 10\%$, 1.20 ohms DC res max; sim to Jeffers 4411-13.		7147161P27		ion: 2.0 ohms ±5%, 1/2 w.	R231H	7147161P22	Composition: 1.2 ohms ±5%, 1/2 w.	W203	19B219998P1	Jumper.
L202L 19C320617P5	Coil.	L220LL	19C320617P15	Coil,	L237H	19C320617P40	Coil.	L254	7480070718	Challe DD 4 70 1 1107 0 00 1 DO		7147161P22		ion: 1.2 ohms ±5%, 1/2 w.	R232LL	7147161P39	Composition: 6.8 ohms ±5%, 1/2 w.	W204	19C320624P1	Strip, connector.
L202M 19C320617P25	Coil.	L220L	19C320617P5	Coil.	L238LL	19C320617P37	Coil.	L255	7488079P12	Choke, RF: 4.70 μh $\pm 10\%$, 0.22 ohms DC res max; sim to Jeffers 4421-3.		3R77P390J		ion: 39 ohms ±5%, 1/2 w.	R232L	7147161P34	Composition: 3.9 ohms ±5%, 1/2 w.	W205		(Part of printed wiring board 19D417923).
L202H 19C320617P4	Coil.	L220M	19C32O617P26	Coil.	L238L	19C320617P38	Coil,	L256	7488079P9	Choke, RF: 2.70 µh ±10%, 1.20 ohms DC res max;	and R215	5K11F3505	Composition	1011. 39 Ohms 13%, 1/2 W.	R232M	7147161P37	Composition: 2.0 ohms ±5%, 1/2 w.	thru W209		
L203 7488079P42	Choke, RF: 8.20 µh ±10%, 0.25 ohms DC res max;	L220H	19C320617P6	Coil.	L238M	19C320617P39	Coil.	and L257		sim to Jeffers 4411-13.	l I	3R78P101J	Compositi	ion: 100 ohms ±5%, 1 w.	R232H	7147161P22	Composition: 1.2 ohms ±5%, 1/2 w.			
100411 10000001707	sim to Jeffers 4422-3.	L221LL	19C320619P1	Coil.	L238H	19C320617P40	Coil.	L258	7488079P10	Choke, RF: 3.30 µh ±10%, 0.15 ohms DC res max;	thru R218	JR76F1013	Compositi	101: 100 01ms 15%, 1 W.	R233LL	714716122	Composition: 6.8 ohms ±5%, 1/2 w.			HEAT SINK ASSEMBLY
L204LL 19C320617P5 L204L 19C320617P26	Coll.	L221L	19C320618P5	Coil,	L239LL	19C320617P37	Coil,			sim to Jeffers 4421-1K.		7147161 P 39	Compositi	ion: 6.8 ohms ±5%, 1/2 w.	R233L	7147161P34	Composition: 3.9 ohms ±5%, 1/2 w.			19B219688G6 M MODEL AND INTERMITTANT DUTY STATION 19B219688G18 E MODEL
L204M 19C320617P27	Cod	L221M	19C320619P5	Coil.	L239L	19C320617P38	Coil.	L259 thru L263	19A129346G1	Coil.	l I	7147161P34		ion: 3.9 ohms ±5%, 1/2 w.	R233M	7147161P27	Composition: 2.0 ohms ±5%, 1/2 w.			CARACITORS
L204H 19C320617P27	Coil	L221H	19C320619P6	Coil.	L239M	19C320617P39	Coil.	L203		TRANSISTORS		7147161P27		ion: 2.0 ohms ±5%, 1/2 w.	R233H	7147161P22	Composition: 1.2 ohms ±5%, 1/2 w.	C297	19A116708P1	
L205LL 19C320617P2	Coil	L222LL	19C320619P1	Coil,	L239H	19C320617P40	Coil.	0911	19A115910P1		R220H			ion: 1.2 ohms ±5%, 1/2 w.	R234LL	7147161P39	Composition: 6.8 ohms ±5%, 1/2 w.	and C298	19411070891	sim to Erie Style 327.
L205L 19C320617P2	Coil.	L222L	19C320618P7	Coil,	L240LL	19C320617P37	Coil.	Q211 Q212	19A115768P1	Silicon, NPN; sim to Type 2N3906.	R221LL			ion: 6.8 ohms ±5%, 1/2 w.	R234L	7147161P34	Composition: 3.9 ohms ±5%, 1/2 w.	C298	19A115680P10	Electrolytic: 200 µf +150% -10%, 18 VDCW; sim
and L205M		L222M	19C320619P5	Coil.	L240L	19C320617P38	Coil.	thru Q214	19811370691	Silicon, PNP; sim to Type 2N3702.		7147161P34		ion: 3.9 ohms ±5%, 1/2 w.	R234M	7147161P27	Composition: 2.0 ohms ±5%, 1/2 w.	0255	194113060F10	to Mallory Type TT.
L205H 19C320618P1	Coil.	L222H	19C320619P6	Coil.	L240M	19C320617P39	Coil.	Q214 Q215	19Al15910Pl	Silicon, NPN; sim to Type 2N3906.		7147161P27		ion: 2.0 ohms ±5%, 1/2 w.	R234H	7147161P22	Composition: 1.2 ohms ±5%, 1/2 w.			DIODES AND RECTIFIERS
L206LL 19C320617P7	Coil.	L223LL		Coil.	L240H	19C320617P40	Coil.		19A115779P1	Silicon, PNP; sim to Type 2N3251.	li I	7147161 P2 2	1	ion: 1.2 ohms ±5%, 1/2 w.	R235LL	7147161P39	Composition: 6.8 ohms ±5%, 1/2 w.	CR295	19Al16783Pl	Silicon.
L206L 19C320617P28	Coil,	L222L	19C320618P7	Coil.	1	19C320617P41	Coil.	Q216	19411017591	officon, PRP, Sim to Type 2N3231.	i i	7147161P39		ion: 6.8 ohms ±5%, 1/2 w.	R235L	7147161P34	Composition: 3.9 ohms ±5%, 1/2 w.	CK250	ISALIOTOSFI	STITEON.
L206M 19C320617P29	Coil.	L222M	19C320619P5	Coil.	L241L	19C320617P42	Coil.					7147161P34		ion: 3.9 ohms ±5%, 1/2 w.	R235M	7147161P27	Composition: 2.0 ohms ±5%, 1/2 w.			MISCELLANEOUS
L206H 19C320617P8	Coil.	L223H	19C320619P6	Coil.	L241M L241H	19C320617P43 19C320617P44	Coil.	R201	3R152P392J	Composition: 3900 ohms $\pm 5\%$, $1/4$ w.	R222M	7147161P27		ion: 2.0 ohms ±5%, 1/2 w.	R235H	7147161P22	Composition: 1.2 ohms ±5%, 1/2 w.		19A129361P1	Shield. (Located between L246 and L247, L247 and
L207LL 19C320617P9	Coil.	L224LL	19C320619P1	Coil.	1	19C320617P41	Coil.	R202	3R152P511J	Composition: 510 ohms $\pm 5\%$, $1/4$ w.	R222H	7147161P22		ion: 1.2 ohms ±5%, 1/2 w.	R236	3R77P390J	Composition: 39 ohms ±5%, 1/2 w.			L248),
L207L 19C320617P30	Coil.	L224L	19C320618P7	Coil.	L242L	19C320617P41	Coil.	R203LL	3R77P120J	Composition: 12 ohms $\pm 5\%$, $1/2$ w.	R223LL	7147161P39		ion: 6.8 ohms ±5%. 1/2 w.	thru R243				19A129361P2	Shield. (Located between L245 and L246).
L207M 1C320617P31	Coil.	L224M	19C320619P5 19C320619P6	Coil.	L242M	19C320617P43	Coil.	R203L	3R77P100J	Composition: 10 ohms ±5%, 1/2 w.	R223L	7147161 P34	Compositi	ion: 3.9 ohms ±5%, 1/2 w.	R244	3R79P101J	Composition: 100 ohms ±5%, 2 w.		19A129810P1	Spacer, phenolic: .047 lD. (Used with L201, L205-L207, L211, L233-L244, L249, L250).
L207H 19C320617P10	Coil.	L224H	i	Coil, Choke, RF: 8.20 µh ±10%, 0.25 ohms DC res max;	L242H	19C320617P44	Coil.	R203M	7147161P42	Composition: 8.2 ohms $\pm 5\%$, $1/2$ w.	R223M	7147161P27	Compositi	ion: 2.0 ohms ±5%, 1/2 w.	thru R246				19A129810P2	Spacer, phenolic: .059 lD. (Used with L201,
L208LL 19C320619P1	Coil.	L225 thru L228	7488079P42	sim to Jeffers 4422-3.	L243LL	19C320617P41	Coil.	R203H		Composition: 4.7 ohms $\pm 5\%$, $1/2$ w.	R223H	7147161P22	Composition	ion: 1.2 ohms ±5%, 1/2 w.	R249	19C320212P2	Shunt resistor.			L202, L204, L207, L208, L210, L214-L224, L229- L232, L237-L244, L249, L250).
L208L 19C320618P7	Coil.	L229LL	19C320617P16	Coil.	L243L	19C320617P42	Coil.	R204LL	3R77P120J	Composition: 12 ohms $\pm 5\%$, $1/2$ w.	R224LL	7147161P39	Compositi	ion: 6.8 ohms ±5%, 1/2 w.	R250	19C320212P1	Shunt resistor.		19B219391P1	Filter casting.
L208M 19C320619P5	Coil.	L229LL L229L	19C320617P16	Coil.	L243M	19C320617P43	Coil.	R204L	3R77P100J	Composition: 10 ohms $\pm 5\%$, 1/2 w.	R224L	7147161P34	Compositi	ion: 3.9 ohms ±5%, 1/2 w.	and R251				19A116022P1	Insulator, bushing. (Used with Q217).
L208H 19C320619P6	Coil.	L229L L229M	19C320617P35	Coil.	L243H	19C320617P44	Coil.	R204M		Composition: 8.2 ohms $\pm 5\%$, $1/2$ w.	R224M	7147161P27	Composition	ion: 2.0 ohms ±5%, 1/2 w.	R252	3R152P153J	Composition: 15,000 ohms $\pm 5\%$, $1/4$ w.		19A116023P1	Insulator, plate. (Used with Q217).
L209 7488079P42	Choke, RF: 8.20 µh ±10%, 0.25 ohms DC res max;	L229M L229H	19C320617P17	Coil.	L244LL	19C320617P41	Coil.	R204H	7147161P13	Composition: 4.7 ohms $\pm 5\%$, $1/2$ w.	R224H	7147161 P 22	Composition	ion: 1.2 ohms ±5%, 1/2 w.	R253	3R152P682J	Composition: 6800 ohms $\pm 5\%$, $1/4$ w.		N5602P015	"O" Ring. (Used with Q217).
	sim to Jeffers 4422-3.	L230LL	19C320617P17	Coil.	L244L	19C320617P42	Coil.	R205 and	3R77P390J	Composition: 39 ohms $\pm 5\%$, $1/2$ w.	R225LL	7147161P39	Compositi	ion: 6.8 ohms ±5%, 1/2 w.	R254	3R152P101J	Composition: 100 ohms $\pm 5\%$, $1/4$ w.		N402P7C6	Washer: No. 6. (Used with Q217).
L210LL 19C320617P11	Coil.	L230LL	19C320617P16	Coil	L244M	19C320617P43	Coil.	R206			R225L	7147161P34	Compositi	ion: 3.9 ohms ±5%, 1/2 w.	R255	19A116278P253	Metal film: 3480 ohms $\pm 2\%$, $1/2$ w.		19Al29888Pl	Insulator. (Used with Q217).
L210L 19C320617P4 and	Coil.	L230L L230M	190320617P12	Coil.	L244H	19C320617P44	Coil.	R207LL	1	Composition: 680 ohms ±5%, 1 w.	R225M	7147161P27	Compositi	ion: 2.0 ohms ±5%, 1/2 w.	R256	19A116278P201	Metal film: 1000 ohms $\pm 2\%$, $1/2$ w.		19D416712P2	Insulator. (Located under Power Amplifier Board).
L210M		L230M	19C320617P17	Coil.	L245LL	19A129360P9	Coil.	R207L		Composition: 680 ohms ±5%, 1 w.	R225H	7147161P22	Compositi	ion: 1.2 ohms ±5%, 1/2 w.	R257	19A116278P261	Metal film: 4220 ohms $\pm 2\%$, $1/2$ w.		19A129661P1	Insulator. (Located at L298).
L210H 19C320617P12	Coil.	L230H L231LL		Coil.	L245L	19A129360P6	Coil.	R207M		Composition: 680 ohms ±5%, 1 w.	R226LL	7147161P39	Compositi	ion: 6.8 ohms ±5%, 1/2 w.	R258	19A116278P269	Metal film: 5110 ohms $\pm 2\%$, $1/2$ w.		19B201074P320	Tap screw, Phillips POZIDRIV [®] : No. 6-32 x 1-1/4.
L211LL 19C320618P6	Coil.	Death.	150520017P10		L245M	19A129360P4	Coil.	R207H	3R78P911J	Composition: 910 ohms ±5%, 1 w.										(Secures Filter Casting).
L211L 19C32068P6 and	Coil.																		5492178P2	Washer, spring tension: sim to Wallace Barnes 375-20. (Used with Q204-Q209).
L211M																			N207P15C6	Hexnut: No. 8-32, (Used with Q204-Q209).
L211H 19C320618P1	Coil.							1											19A129434P1	Washer. (Used with C297, C298).
L214LL 19C320617P13	Coil.				1				l				4		1			11		
L214L 19C320617P32	Coil.									1					1					

LBI-4898

PRODUCTION CHANGES

Changes in the equipment to improve performance or to simplify circuits are identified by a "Revision Letter", which is stamped after the model number of the unit. The revision stamped on the unit includes all previous revisions. Refer to the Parts List for descriptions of parts affected by these revisions.

- REV. A Power Amplifier Board 19D417927G1-4
 - To improve operation. Changed CR201.
- REV. B To improve stopband attenuation (25-30 MHz range) Changed C4201LL and C4205LL.